Advance Information

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MPC875/MPC870 Hardware Specifications



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This hardware specification contains detailed information on power considerations, DC/AC electrical characteristics, and AC timing specifications for the MPC875/MPC870. The CPU on the MPC875/MPC870 is a 32-bit PowerPCTM core that incorporates memory management units (MMUs) and instruction and data caches and that implements the PowerPC instruction set. This hardware specification covers the following topics:

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1 Overview

The MPC875/MPC870 is a versatile single-chip integrated microprocessor and peripheral combination that can be used in a variety of controller applications and communications and networking systems. The MPC875/MPC870 provides enhanced ATM functionality over that of other ATM-enabled members of the MPC860 family. Table 1 shows the functionality supported by the members of the MPC875/MPC870.

Part	Cache		Ethe	rnet	SCC	500	SMC	USB	Security
Tart	I Cache	D Cache	10BaseT	10/100	000	SINC	035	Engine	
MPC875	8 Kbyte	8 Kbyte	1	2	1	1	1	Yes	
MPC870	8 Kbyte	8 Kbyte	—	2	—	1	1	No	

Table 1. MPC875/870 Devices

2 Features

The MPC875/870 is comprised of three modules that each use the 32-bit internal bus: the MPC8xx core, the system integration unit (SIU), and the communication processor module (CPM).

The following list summarizes the key MPC875/870 features:

- Embedded MPC8xx core up to 120 MHz
- Maximum frequency operation of the external bus is 80 MHz (in 1:1 mode)
 - The 120-MHz core frequency supports 2:1 mode only.
 - The 66-/80-MHz core frequencies support both 1:1 and 2:1 modes.
- Single-issue, 32-bit core (compatible with the PowerPC architecture definition) with thirty-two 32-bit general-purpose registers (GPRs)
 - The core performs branch prediction with conditional prefetch, without conditional execution
 - 8-Kbyte data cache and 8-Kbyte instruction cache (see Table 1)
 - 8-Kbyte instruction cache is two-way, set-associative with 256 sets in two blocks
 - 8-Kbyte data cache is two-way, set-associative with 256 sets
 - Cache coherency for both instruction and data caches is maintained on 128-bit (4-word) cache blocks
 - Caches are physically addressed, implement a least recently used (LRU) replacement algorithm, and are lockable on a cache block basis.
 - MMUs with 32-entry TLB, fully-associative instruction and data TLBs
 - MMUs support multiple page sizes of 4, 16, and 512 Kbytes, and 8 Mbytes; 16 virtual address spaces and 16 protection groups
 - Advanced on-chip emulation debug mode
- Up to 32-bit data bus (dynamic bus sizing for 8, 16, and 32 bits)
- 32 address lines
- Memory controller (eight banks)
 - Contains complete dynamic RAM (DRAM) controller
 - Each bank can be a chip select or \overline{RAS} to support a DRAM bank.
 - Up to 30 wait states programmable per memory bank

- Glueless interface to DRAM, SIMMS, SRAM, EPROMs, Flash EPROMs, and other memory devices
- DRAM controller programmable to support most size and speed memory interfaces
- Four \overline{CAS} lines, four \overline{WE} lines, one \overline{OE} line
- Boot chip-select available at reset (options for 8-, 16-, or 32-bit memory)
- Variable block sizes (32 Kbyte–256 Mbyte)
- Selectable write protection
- On-chip bus arbitration logic
- General-purpose timers
 - Four 16-bit timers or two 32-bit timers
 - Gate mode can enable/disable counting
 - Interrupt can be masked on reference match and event capture
- Two fast Ethernet controllers (FEC)—two 10/100 Mbps Ethernet/IEEE 802.3 CDMA/CS interface through MII and/or RMII interfaces
- System integration unit (SIU)
 - Bus monitor
 - Software watchdog
 - Periodic interrupt timer (PIT)
 - Clock synthesizer
 - Decrementer and time base
 - Reset controller
 - IEEE 1149.1 test access port (JTAG)
- Security engine is optimized to handle all the algorithms associated with IPsec, SSL/TLS, SRTP, 802.11i, and iSCSI processing. Available on the MPC875, the security engine contains a crypto-channel, a controller, and a set of crypto hardware accelerators (CHAs). The CHAs are:
 - Data encryption standard execution unit (DEU)
 - DES, 3DES
 - Two key (K1, K2, K1) or three key (K1, K2, K3)
 - ECB and CBC modes for both DES and 3DES
 - Advanced encryption standard unit (AESU)
 - Implements the Rinjdael symmetric key cipher
 - ECB, CBC, and counter modes
 - 128-, 192-, and 256-bit key lengths
 - Message digest execution unit (MDEU)
 - SHA with 160- or 256-bit message digest
 - MD5 with 128-bit message digest
 - HMAC with either algorithm
 - Master/slave logic, with DMA
 - 32-bit address/32-bit data
 - Operation at 8xx bus frequency

Features

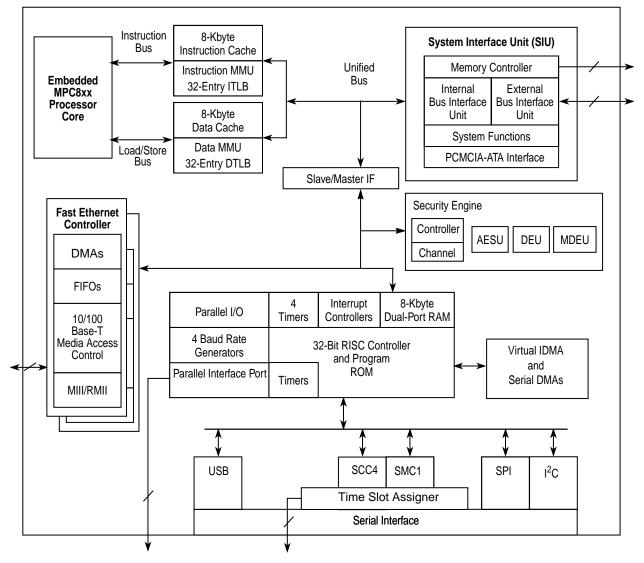
- Crypto-channel supporting multi-command descriptors
 - Manages crypto-execution units through an integrated controller
 - Buffer size of 256 bytes for each execution unit, with flow control for large data sizes
- Interrupts
 - Six external interrupt request (IRQ) lines
 - 12 port pins with interrupt capability
 - 23 internal interrupt sources
 - Programmable priority between SCCs
 - Programmable highest priority request
- Communications processor module (CPM)
 - RISC controller
 - Communication-specific commands (for example, GRACEFUL STOP TRANSMIT, ENTER HUNT MODE, and RESTART TRANSMIT)
 - Supports continuous mode transmission and reception on all serial channels
 - 8-Kbytes of dual-port RAM
 - Several serial DMA (SDMA) channels to support the CPM
 - Three parallel I/O registers with open-drain capability
- On-chip 16×16 multiply accumulate controller (MAC)
 - One operation per clock (two-clock latency, one-clock blockage)
 - MAC operates concurrently with other instructions
 - FIR loop: four clocks per four multiplies
- Four baud-rate generators
 - Independent (can be connected to any SCC or SMC)
 - Allows changes during operation
 - Autobaud support option
- One SCC (serial communication controller).
 - Ethernet/IEEE 802.3 optional on the SCC, supporting full 10-Mbps operation
 - HDLC/SDLC
 - HDLC bus (implements an HDLC-based local area network (LAN))
 - Asynchronous HDLC to support point-to-point protocol (PPP)
 - AppleTalk
 - Universal asynchronous receiver transmitter (UART)
 - Synchronous UART
 - Serial infrared (IrDA)
 - Binary synchronous communication (BISYNC)
 - Totally transparent (bit streams)
 - Totally transparent (frame based with optional cyclic redundancy check (CRC))
- One SMC (serial management channel)
 - UART
 - Transparent

- Universal serial bus (USB)—supports operation as a USB function endpoint, a USB host controller, or both for testing purposes (loop-back diagnostics)
 - USB 2.0 full-/low-speed compatible
 - The USB function mode has the following features:
 - Four independent endpoints support control, bulk, interrupt, and isochronous data transfers.
 - CRC16 generation and checking
 - CRC5 checking
 - NRZI encoding/decoding with bit stuffing
 - 12- or 1.5-Mbps data rate
 - Flexible data buffers with multiple buffers per frame
 - Automatic retransmission upon transmit error
 - The USB host controller has the following features:
 - Supports control, bulk, interrupt, and isochronous data transfers
 - CRC16 generation and checking
 - NRZI encoding/decoding with bit stuffing
 - Supports both 12- and 1.5-Mbps data rates (automatic generation of preamble token and data rate configuration). Note that low-speed operation requires an external hub.
 - Flexible data buffers with multiple buffers per frame
 - Supports local loop back mode for diagnostics (12 Mbps only)
- One serial peripheral interface (SPI)
 - Supports master and slave modes
 - Supports multiple master operation on the same bus
- One inter-integrated circuit (I²C) port
 - Supports master and slave modes
 - Multiple-master environment support
- The MPC875 has a time-slot assigner (TSA) that supports one TDM bus (TDMb)
 - Allows SCC and SMC to run in multiplexed and/or non-multiplexed operation
 - Supports T1, CEPT, PCM highway, ISDN basic rate, ISDN primary rate, user defined
 - 1- or 8-bit resolution
 - Allows independent transmit and receive routing, frame synchronization, and clocking
 - Allows dynamic changes
 - Can be internally connected to two serial channels (one SCC and one SMC)
- One PCMCIA interface
 - Master (socket) interface, release 2.1-compliant
 - Supports one independent PCMCIA socket on the MPC875/MPC870
 - 8 memory or I/O windows supported
- Debug interface
 - Eight comparators: four operate on instruction address, two operate on data address, and two
 operate on data
 - Supports conditions: = $\neq <>$
 - Each watchpoint can generate a break point internally.

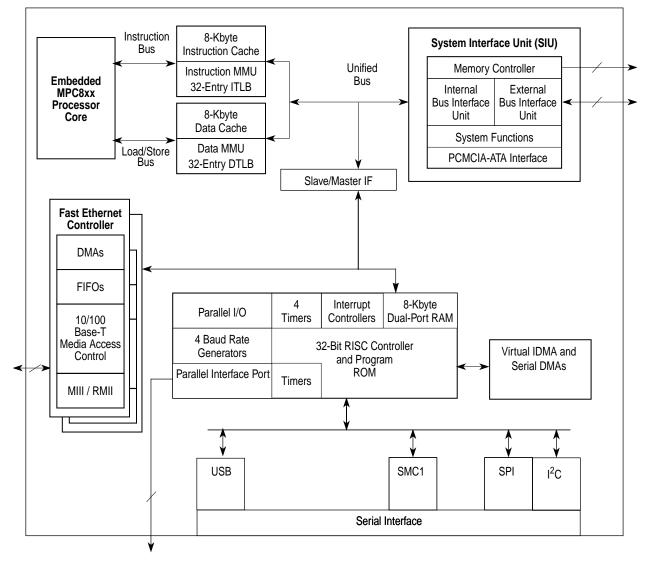
Features

- Normal high and normal low power modes to conserve power
- 1.8-V core and 3.3-V I/O operation with 5-V TTL compatibility
- The MPC875/870 comes in a 256-pin PBGA package.

The MPC875 block diagram is shown in Figure 1.







The MPC870 block diagram is shown in Figure 2.

Figure 2. MPC870 Block Diagram

3 Maximum Tolerated Ratings

This section provides the maximum tolerated voltage and temperature ranges for the MPC875/870. Table 2 displays the maximum tolerated ratings, and Table 3 displays the operating temperatures.

Rating	Symbol	Value	Unit
Supply voltage ¹	VDDL (core voltage)	e -0.3 to 3.4	V
	VDDH (I/C voltage)	-0.3 to 4	V
	VDDSYN	-0.3 to 3.4	V
	Difference between VDDL and VDDSYN	<100	mV
Input voltage ²	V _{in}	GND-0.3 to VDDH	V
Storage temperature range	T _{stg}	-55 to +150	°C

Table 2. Maximum Tolerated Ratings

 $^{1}\,$ The power supply of the device must start its ramp from 0.0 V.

² Functional operating conditions are provided with the DC electrical specifications in Table 6. Absolute maximum ratings are stress ratings only; functional operation at the maxima is not guaranteed. Stress beyond those listed may affect device reliability or cause permanent damage to the device.

Caution: All inputs that tolerate 5 V cannot be more than 2.5 V greater than VDDH. This restriction applies to power up and normal operation (that is, if the MPC875/870 is unpowered, a voltage greater than 2.5 V must not be applied to its inputs).

Table 3	3. Operating Tempera	atures
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Rating	Symbol	Value	Unit
Temperature ¹ (standard)	T _{A(min)}	0	°C
	T _{j(max)}	95	°C
Temperature (extended)	T _{A(min)}	-40	°C
	T _{j(max)}	100	°C

¹ Minimum temperatures are guaranteed as ambient temperature, T_A. Maximum temperatures are guaranteed as junction temperature, T_i.

This device contains circuitry protecting against damage due to high-static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for example, either GND or VDDH).

4 Thermal Characteristics

Table 4 shows the thermal characteristics for the MPC875/870.

Table 4. MPC875/870 Thermal Resistance) Data
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Rating	En	Symbol	Value	Unit	
Junction-to-ambient ¹	Natural convection	Single-layer board (1s)	R _{0JA} ²	49	°C/W
		Four-layer board (2s2p)	$R_{\theta JMA}^{3}$	32	
	Airflow (200 ft/min)	Single-layer board (1s)	$R_{\theta JMA}{}^3$	41	
		Four-layer board (2s2p)	$R_{\theta JMA}^{3}$	29	
Junction-to-board ⁴			$R_{\theta JB}$	24	
Junction-to-case 5			$R_{ extsf{ heta}JC}$	13	
Junction-to-package top ⁶	Natural convection		Ψ _{JT}	3	1
	Airflow (200 ft/min)		Ψ_{JT}	2]

¹ Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, airflow, power dissipation of other components on the board, and board thermal resistance.

- ² Per SEMI G38-87 and JEDEC JESD51-2 with the single-layer board horizontal
- ³ Per JEDEC JESD51-6 with the board horizontal
- ⁴ Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
- ⁵ Indicates the average thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1) with the cold plate temperature used for the case temperature. For exposed pad packages where the pad would be expected to be soldered, junction-to-case thermal resistance is a simulated value from the junction to the exposed pad without contact resistance.
- ⁶ Thermal characterization parameter indicating the temperature difference between the package top and the junction temperature per JEDEC JESD51-2

5 **Power Dissipation**

Table 5 provides information on power dissipation. The modes are 1:1, where CPU and bus speeds are equal, and 2:1, where CPU frequency is twice bus speed.

Die Revision	Bus Mode	Frequency	Typical ¹	Maximum ²	Unit
		66 MHz	TBD	TBD	mW
0	1:1	80 MHz	TBD	TBD	mW
	2:1	120 MHz	TBD	TBD	mW

Table 5. Power Dissipation (P_D)

¹ Typical power dissipation is measured at 1.9 V.

² Maximum power dissipation at VDDL and VDDSYN is at 1.9 V, and VDDH is at 3.465 V.

NOTE

Values in Table 5 represent VDDL-based power dissipation and do not include I/O power dissipation over VDDH. I/O power dissipation varies widely by application due to buffer current, depending on external circuitry.

The VDDSYN power dissipation is negligible.

6 DC Characteristics

Table 6 provides the DC electrical characteristics for the MPC875/870.

Table 6. DC Electrical Specifications

Characteristic	Symbol	Min	Max	Unit
Operating voltage	VDDH (I/O)	3.135	3.465	V
	VDDL (Core)	1.7	1.9	V
	VDDSYN ¹	1.7	1.9	V
	Difference between VDDL and VDDSYN	_	100	mV
Input high voltage (all inputs except PA[0:3], PA[8:11], PB15, PB[24:25]; PB[28:31], PC[4:7], PC[12:13], PC15, PD[3:15], TDI, TDO, TCK, TRST, TMS, MII_TXEN, MII_MDIO) ²	VIH	2.0	3.465	V

Characteristic	Symbol	Min	Max	Unit
Input low voltage	VIL	GND	0.8	V
EXTAL, EXTCLK input high voltage	VIHC	$0.7 \times VDDH$	VDDH	V
Input leakage current, Vin = 5.5 V (except TMS, $\overline{\text{TRST}}$, DSCK and DSDI pins) for 5-V tolerant pins ¹	l _{in}	_	100	μA
Input leakage current, Vin = VDDH (except TMS, $\overline{\text{TRST}}$, DSCK, and DSDI)	l _{in}	_	10	μA
Input leakage current, Vin = 0V (except TMS, TRST, DSCK and DSDI pins)	l _{in}	_	10	μA
Input capacitance ³	C _{in}	—	20	pF
Output high voltage, IOH = -2.0 mA, VDDH = $3.0V$ except XTAL and open-drain pins	VOH	2.4	—	V
Output low voltage IOL = 2.0 mA (CLKOUT) IOL = 3.2 mA IOL = 5.3 mA IOL = 7.0 mA (TXD1/PA14, TXD2/PA12) IOL = 8.9 mA (TS, TA, TEA, \overline{BI} , \overline{BB} , \overline{HRESET} , \overline{SRESET})	VOL	—	0.5	V

Table 6. DC Electrical Specifications (continued)

¹ The difference between VDDL and VDDSYN cannot be more than 100 mV.

² The PA[0:3], PA[8:11], PB15, PB[24:25]; PB[28:31], PC[4:7], PC[12:13], PC15, PD[3:15], TDI, TDO, TCK, TRST, TMS, MII_TXEN, MII_MDIO are 5-V tolerant pins. The minimum voltage is still 2.0 V.

³ Input capacitance is periodically sampled.

7 Thermal Calculation and Measurement

For the following discussions, $P_D = (VDDL \times IDDL) + P_{I/O}$, where $P_{I/O}$ is the power dissipation of the I/O drivers.

NOTE

The VDDSYN power dissipation is negligible.

7.1 Estimation with Junction-to-Ambient Thermal Resistance

An estimation of the chip junction temperature, T_J, in °C can be obtained from the equation:

 $T_J = T_A + (R_{\theta JA} \times P_D)$

where:

 T_A = ambient temperature °C

 $R_{\theta JA}$ = package junction-to-ambient thermal resistance (°C/W)

 P_D = power dissipation in package

The junction-to-ambient thermal resistance is an industry standard value that provides a quick and easy estimation of thermal performance. However, the answer is only an estimate; test cases have demonstrated that errors of a factor of two (in the quantity T_{J} - T_{A}) are possible.

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7.2 Estimation with Junction-to-Case Thermal Resistance

Historically, thermal resistance has frequently been expressed as the sum of a junction-to-case thermal resistance and a case-to-ambient thermal resistance:

 $R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$

where:

 $R_{\theta JA}$ = junction-to-ambient thermal resistance (°C/W)

 $R_{\theta JC}$ = junction-to-case thermal resistance (°C/W)

 $R_{\theta CA}$ = case-to-ambient thermal resistance (°C/W)

 $R_{\theta JC}$ is device-related and cannot be influenced by the user. The user adjusts the thermal environment to affect the case-to-ambient thermal resistance, $R_{\theta CA}$. For instance, the user can change the airflow around the device, add a heat sink, change the mounting arrangement on the printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device. This thermal model is most useful for ceramic packages with heat sinks where some 90% of the heat flows through the case and the heat sink to the ambient environment. For most packages, a better model is required.

7.3 Estimation with Junction-to-Board Thermal Resistance

A simple package thermal model which has demonstrated reasonable accuracy (about 20%) is a two-resistor model consisting of a junction-to-board and a junction-to-case thermal resistance. The junction-to-case thermal resistance covers the situation where a heat sink is used or where a substantial amount of heat is dissipated from the top of the package. The junction-to-board thermal resistance describes the thermal performance when most of the heat is conducted to the printed circuit board. It has been observed that the thermal performance of most plastic packages and especially PBGA packages is strongly dependent on the board temperature. If the board temperature is known, an estimate of the junction temperature in the environment can be made using the following equation:

 $T_J = T_B + (R_{\theta JB} \times P_D)$

where:

 $R_{\theta JB}$ = junction-to-board thermal resistance (°C/W)

 T_B = board temperature °C

 P_D = power dissipation in package

If the board temperature is known and the heat loss from the package case to the air can be ignored, acceptable predictions of junction temperature can be made. For this method to work, the board and board mounting must be similar to the test board used to determine the junction-to-board thermal resistance, namely a 2s2p (board with a power and a ground plane) and vias attaching the thermal balls to the ground plane.

7.4 Estimation Using Simulation

When the board temperature is not known, a thermal simulation of the application is needed. The simple two-resistor model can be used with the thermal simulation of the application [2], or a more accurate and complex model of the package can be used in the thermal simulation.

7.5 Experimental Determination

To determine the junction temperature of the device in the application after prototypes are available, the thermal characterization parameter (Ψ_{JT}) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using the following equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

where:

 Ψ_{JT} = thermal characterization parameter

 T_T = thermocouple temperature on top of package

 P_D = power dissipation in package

The thermal characterization parameter is measured per JESD51-2 specification published by JEDEC using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

7.6 References

Semiconductor Equipment and Materials International 805 East Middlefield Rd Mountain View, CA 94043	(415) 964-5111
MIL-SPEC and EIA/JESD (JEDEC) specifications (Available from Global Engineering Documents)	800-854-7179 or 303-397-7956
JEDEC Specifications	http://www.jedec.org

1. C.E. Triplett and B. Joiner, "An Experimental Characterization of a 272 PBGA Within an Automotive Engine Controller Module," Proceedings of SemiTherm, San Diego, 1998, pp. 47-54.

2. B. Joiner and V. Adams, "Measurement and Simulation of Junction to Board Thermal Resistance and Its Application in Thermal Modeling," Proceedings of SemiTherm, San Diego, 1999, pp. 212-220.

8 Power Supply and Power Sequencing

This section provides design considerations for the MPC875/870 power supply. The MPC875/870 has a core voltage (VDDL) and PLL voltage (VDDSYN) which operates at a lower voltage than the I/O voltage VDDH. The I/O section of the MPC875/870 is supplied with 3.3 V across VDDH and V_{SS} (GND).

The signals PA[0:3], PA[8:11], PB15, PB[24:25]; PB[28:31], PC[4:7], PC[12:13], PC15] PD[3:15], TDI, TDO, TCK, TRST, TMS, MII_TXEN, MII_MDIO are 5-V tolerant. All inputs cannot be more than 2.5 V greater than VDDH. In addition, 5 V-tolerant pins cannot exceed 5.5 V, and remaining input pins cannot exceed 3.465 V. This restriction applies to power up/down and normal operation.

One consequence of multiple power supplies is that when power is initially applied the voltage rails ramp up at different rates. The rates depend on the nature of the power supply, the type of load on each power supply, and the manner in which different voltages are derived. The following restrictions apply:

- VDDL must not exceed VDDH during power up and power down.
- VDDL must not exceed 1.9 V, and VDDH must not exceed 3.465.

Mandatory Reset Configurations

These cautions are necessary for the long-term reliability of the part. If they are violated, the electrostatic discharge (ESD) protection diodes are forward-biased, and excessive current can flow through these diodes. If the system power supply design does not control the voltage sequencing, the circuit shown can be added to meet these requirements. The MUR420 Schottky diodes control the maximum potential difference between the external bus and core power supplies on power up, and the 1N5820 diodes regulate the maximum potential difference on power down.

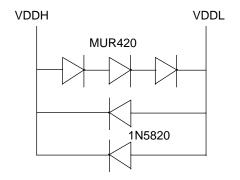


Figure 3. Example Voltage Sequencing Circuit

9 Mandatory Reset Configurations

The MPC875/870 requires a mandatory configuration during reset.

If Hardware Reset Configuration Word (HRCW) is enabled, by asserting the RSTCONF during HRESET assertion, the HRCW[DBGC] value needed to be set to binary 01 in the Hardware Reset Configuration Word (HRCW) and the SIUMCR[DBGC] should be programmed with the same value in the boot code after reset.

If Hardware Reset Configuration Word (HRCW) is disabled, by negating the $\overline{\text{RSTCONF}}$ during the $\overline{\text{HRESET}}$ assertion, the SIUMCR[DBGC] should be programmed with binary 11 in the boot code after reset.

The MBMR[GPLB4DIS], PAPAR, PADIR, PBPAR, PBDIR, PCPAR, and PCDIR need to be configured with the mandatory values in Table 7 in the boot code after the reset deasserts.

Register/Configuration	Field	Value (binary)
HRCW (Hardware reset configuration word)	HRCW[DBGC]	01
SIUMCR (SIU module configuration register)	SIUMCR[DBGC]	01
MBMR (Machine B mode register)	MBMR[GPLB4DIS}	0
PAPAR (Port A pin assignment register)	PAPAR[5-9] PAPAR[12-13]	0
PADIR (Port A data direction register)	PADIR[5-9] PADIR[12-13]	0

Table 7. Mandatory Reset Configuration of MPC875/870

Register/Configuration	Field	Value (binary)
PBPAR (Port B pin assignment register)	PBPAR[14-18] PBPAR[20-22]	0
PBDIR (Port B data direction register)	PBDIR[14-18] PBDIR[20-22]	0
PCPAR (Port C pin assignment register)	PCPAR[4-5] PCPAR[8-9] PCPAR[14]	0
PCDIR (Port C data direction register)	PCDIR[4-5] PCDIR[8-9] PCDIR[14]	0
PDPAR (Port D pin assignment register)	PDPAR[3-7] PDPAR[9-15]	0
PDDIR (Port D data direction register)	PDDIR[3-7] PDDIR[9-15]	0

Table 7. Mandatory Reset Configuration of MPC875/870 (continued)

10 Layout Practices

Each V_{DD} pin on the MPC875/870 should be provided with a low-impedance path to the board's supply. Each GND pin should likewise be provided with a low-impedance path to ground. The power supply pins drive distinct groups of logic on chip. The V_{DD} power supply should be bypassed to ground using at least four 0.1 µF by-pass capacitors located as close as possible to the four sides of the package. Each board designed should be characterized and additional appropriate decoupling capacitors should be used if required. The capacitor leads and associated printed circuit traces connecting to chip V_{DD} and GND should be kept to less than half an inch per capacitor lead. At a minimum, a four-layer board employing two inner layers as V_{DD} and GND planes should be used.

All output pins on the MPC875/870 have fast rise and fall times. Printed circuit (PC) trace interconnection length should be minimized in order to minimize undershoot and reflections caused by these fast output switching times. This recommendation particularly applies to the address and data buses. Maximum PC trace lengths of six inches are recommended. Capacitance calculations should consider all device loads as well as parasitic capacitances due to the PC traces. Attention to proper PCB layout and bypassing becomes especially critical in systems with higher capacitive loads because these loads create higher transient currents in the V_{DD} and GND circuits. Pull up all unused inputs or signals that will be inputs during reset. Special care should be taken to minimize the noise levels on the PLL supply pins. For more information, please refer to the *MPC866 PowerQUICC Family User's Manual*, section, "Clock Synthesizer Power (VDDSYN, VSSSYN, VSSSYN1)."

11 Bus Signal Timing

The maximum bus speed supported by the MPC875/870 is 80 MHz. Higher-speed parts must be operated in half-speed bus mode (for example, an MPC875/870 used at 120 MHz must be configured for a 60 MHz bus). Table 8 shows the frequency ranges for standard part frequencies in 1:1 bus mode, and Table 9 shows the frequency ranges for standard part frequencies in 2:1 bus mode.

Part Frequency	66 I	MHz	80 MHz		
	Min	Мах	Min	Max	
Core frequency	40	66.67	40	80	
Bus frequency	40	66.67	40	80	

Table 8. Frequency Ranges for Standard Part Frequencies (1:1 Bus Mode)

Table 9. Frequency Ranges for Standard Part Frequencies (2:1 Bus Mode)

Part Frequency	Part Frequency 66 MHz 80 MHz 120 M				MHz	
	Min Max		Min	Мах	Min	Max
Core frequency	40	66.67	40	80	40	120
Bus frequency	20	33.33	20	40	20	60

Table 10 provides the bus operation timing for the MPC875/870 at 33 MHz, 40 Mhz, 66 MHz and 80 Mhz.

The timing for the MPC875/870 bus shown assumes a 50-pF load for maximum delays and a 0-pF load for minimum delays. CLKOUT assumes a 100-pF load maximum delay

Num	Characteristic	33	MHz	40 I	MHz	66 I	MHz	80 MHz		Unit
Num	Cildiacteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B1	Bus period (CLKOUT), see Table 8	—	—	—	—	_	—	—		ns
B1a	EXTCLK to CLKOUT phase skew	-2	+2	-2	+2	-2	+2	-2	+2	ns
B1b	CLKOUT frequency jitter peak-to-peak	_	1	—	1	_	1	—	1	ns
B1c	Frequency jitter on EXTCLK	_	0.50	—	0.50	_	0.50	—	0.50	%
B1d	CLKOUT phase jitter peak-to-peak for OSCLK \ge 15 MHz	_	4	_	4	_	4	_	4	ns
	CLKOUT phase jitter peak-to-peak for OSCLK < 15 MHz		5		5	_	5	—	5	ns
B2	CLKOUT pulse width low (MIN = $0.4 \times B1$, MAX = $0.6 \times B1$)	12.1	18.2	10.0	15.0	6.1	9.1	5.0	7.5	ns
B3	CLKOUT pulse width high (MIN = $0.4 \times$ B1, MAX = $0.6 \times$ B1)	12.1	18.2	10.0	15.0	6.1	9.1	5.0	7.5	ns
B4	CLKOUT rise time	—	4.00	_	4.00	_	4.00	—	4.00	ns
B5	CLKOUT fall time	—	4.00	_	4.00	_	4.00	—	4.00	ns
B7	CLKOUT to A(0:31), BADDR(28:30), RD/WR, BURST, D(0:31) output hold (MIN = $0.25 \times B1$)	7.60	_	6.30	_	3.80	_	3.125		ns
B7a	CLKOUT to TSIZ(0:1), $\overline{\text{REG}}$, $\overline{\text{RSV}}$, $\overline{\text{BDIP}}$, PTR output hold (MIN = 0.25 × B1)	7.60	—	6.30	—	3.80	—	3.125	_	ns

Table 10. Bus Operation Timings

Num	Characteristic	33	MHz	40	MHz	66	MHz	80 MHz		Unit
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B7b	CLKOUT to \overline{BR} , \overline{BG} , FRZ, VFLS(0:1), VF(0:2) IWP(0:2), LWP(0:1), \overline{STS} output hold (MIN = 0.25 × B1)	7.60		6.30		3.80	_	3.125		ns
B8	CLKOUT to A(0:31), BADDR(28:30) RD/WR, BURST, D(0:31) valid (MAX = 0.25 × B1 + 6.3)		13.80	_	12.50	_	10.00		9.425	ns
B8a	CLKOUT to TSIZ(0:1), $\overline{\text{REG}}$, $\overline{\text{RSV}}$, $\overline{\text{BDIP}}$, PTR valid (MAX = 0.25 × B1 + 6.3)	_	13.80	_	12.50	_	10.00	_	9.425	ns
B8b	CLKOUT to \overline{BR} , \overline{BG} , VFLS(0:1), VF(0:2), IWP(0:2), FRZ, LWP(0:1), \overline{STS} Valid ² (MAX = 0.25 × B1 + 6.3)		13.80	_	12.50	_	10.00		9.425	ns
B9	CLKOUT to A(0:31), BADDR(28:30), RD/WR, BURST, D(0:31), TSIZ(0:1), REG, RSV, PTR High-Z (MAX = 0.25 × B1 + 6.3)	7.60	13.80	6.30	12.50	3.80	10.00	TBD	9.425	ns
B11	CLKOUT to \overline{TS} , \overline{BB} assertion (MAX = 0.25 \times B1 + 6.0)	7.60	13.60	6.30	12.30	3.80	9.80	TBD	9.125	ns
B11a	CLKOUT to \overline{TA} , \overline{BI} assertion (when driven by the memory controller or PCMCIA interface) (MAX = $0.00 \times B1 + 9.30^{1}$)	2.50	9.30	2.50	9.30	2.50	9.80	2.5	9.3	ns
B12	CLKOUT to \overline{TS} , \overline{BB} negation (MAX = 0.25 \times B1 + 4.8)	7.60	12.30	6.30	11.00	3.80	8.50	TBD	7.92	ns
B12a	CLKOUT to \overline{TA} , \overline{BI} negation (when driven by the memory controller or PCMCIA interface) (MAX = 0.00 × B1 + 9.00)	2.50	9.00	2.50	9.00	2.50	9.00	2.5	9.00	ns
B13	CLKOUT to \overline{TS} , \overline{BB} High-Z (MIN = 0.25 × B1)	7.60	21.60	6.30	20.30	3.80	14.00	3.125	TBD	ns
B13a	CLKOUT to \overline{TA} , \overline{BI} High-Z (when driven by the memory controller or PCMCIA interface) (MIN = 0.00 × B1 + 2.5)	2.50	15.00	2.50	15.00	2.50	15.00	2.5	TBD	ns
B14	CLKOUT to $\overline{\text{TEA}}$ assertion (MAX = 0.00 × B1 + 9.00)	2.50	9.00	2.50	9.00	2.50	9.00	2.50	9.00	ns
B15	CLKOUT to $\overline{\text{TEA}}$ High-Z (MIN = 0.00 × B1 + 2.50)	2.50	15.00	2.50	15.00	2.50	15.00	2.50	TBD	ns
B16	$\overline{\text{TA}}$, $\overline{\text{BI}}$ valid to CLKOUT (setup time) (MIN = 0.00 × B1 + 6.00)	6.00	_	6.00	—	6.00	-	6	_	ns
B16a	TEA, $\overline{\text{KR}}$, $\overline{\text{RETRY}}$, $\overline{\text{CR}}$ valid to CLKOUT (setup time) (MIN = 0.00 × B1 + 4.5)	4.50	_	4.50	-	4.50	-	4.50	_	ns
B16b	$\overline{\text{BB}}, \overline{\text{BG}}, \overline{\text{BR}}, \text{ valid to CLKOUT (setup time)}$ ² (4MIN = 0.00 × B1 +.000)	4.00	-	4.00	—	4.00	-	4.00	_	ns
B17	CLKOUT to \overline{TA} , \overline{TEA} , \overline{BI} , \overline{BB} , \overline{BG} , \overline{BR} valid (hold time) (MIN = 0.00 × B1 + 1.00 ³)	1.00	-	1.00	-	2.00	-	2.00	_	ns

		33	MHz	40 I	MHz	66 I	MHz	80	MHz	
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B17a	CLKOUT to $\overline{\text{KR}}$, $\overline{\text{RETRY}}$, $\overline{\text{CR}}$ valid (hold time) (MIN = 0.00 × B1 + 2.00)	2.00	_	2.00	_	2.00	_	2.00	_	ns
B18	D(0:31) valid to CLKOUT rising edge (setup time) 4 (MIN = 0.00 × B1 + 6.00)	6.00		6.00	_	6.00		6.00	_	ns
B19	CLKOUT rising edge to D(0:31) valid (hold time) 4 (MIN = 0.00 × B1 + 1.00 5)	1.00	_	1.00	_	2.00	_	TBD	—	ns
B20	D(0:31) valid to CLKOUT falling edge (setup time) 6 (MIN = 0.00 × B1 + 4.00)	4.00	_	4.00	_	4.00	_	4.00	-	ns
B21	CLKOUT falling edge to D(0:31) valid (hold Time) 6 (MIN = 0.00 × B1 + 2.00)	2.00	_	2.00	_	2.00	_	2.00	-	ns
B22	CLKOUT rising edge to \overline{CS} asserted GPCM ACS = 00 (MAX = 0.25 × B1 + 6.3)	7.60	13.80	6.30	12.50	3.80	10.00	TBD	9.425	ns
B22a	CLKOUT falling edge to \overline{CS} asserted GPCM ACS = 10, TRLX = 0 (MAX = 0.00 \times B1 + 8.00)		8.00		8.00		8.00		8.00	ns
B22b	CLKOUT falling edge to \overline{CS} asserted GPCM ACS = 11, TRLX = 0, EBDF = 0 (MAX = 0.25 × B1 + 6.3)	7.60	13.80	6.30	12.50	3.80	10.00	TBD	9.425	ns
B22c	CLKOUT falling edge to \overline{CS} asserted GPCM ACS = 11, TRLX = 0, EBDF = 1 (MAX = 0.375 × B1 + 6.6)	10.90	18.00	10.90	16.00	5.20	12.30	TBD	10.92 5	ns
B23	CLKOUT rising edge to \overline{CS} negated GPCM read access, GPCM write access ACS = 00, TRLX = 0 & CSNT = 0 (MAX = 0.00 × B1 + 8.00)	2.00	8.00	2.00	8.00	2.00	8.00	2.00	8.00	ns
B24	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 10, TRLX = 0 (MIN = 0.25 × B1 - 2.00)	5.60		4.30		1.80		TBD	—	ns
B24a	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 11 TRLX = 0 (MIN = 0.50 × B1 - 2.00)	13.20		10.50		5.60		4.25	_	ns
B25	CLKOUT rising edge to \overline{OE} , WE(0:3)/BS_B[0:3] asserted (MAX = 0.00 \times B1 + 9.00)		9.00		9.00		9.00		9.00	ns
B26	CLKOUT rising edge to \overline{OE} negated (MAX = 0.00 × B1 + 9.00)	2.00	9.00	2.00	9.00	2.00	9.00	2.00	9.00	ns
B27	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 10, TRLX = 1 (MIN = 1.25 × B1 - 2.00)	35.90		29.30		16.90		13.60		ns
B27a	A(0:31) and BADDR(28:30) to \overline{CS} asserted GPCM ACS = 11, TRLX = 1 (MIN = 1.50 × B1 - 2.00)	43.50		35.50		20.70		16.75		ns

NI	Ohenneterietie	33	MHz	40 I	MHz	66 I	MHz	80	MHz	Unit
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B28	CLKOUT rising edge to $\overline{WE}(0:3)/BS_B[0:3]$ negated GPCM write access CSNT = 0 (MAX = 0.00 × B1 + 9.00)		9.00		9.00		9.00		9.00	ns
B28a	CLKOUT falling edge to $\overline{WE}(0:3)/BS_B[0:3]$ negated GPCM write access TRLX = 0, CSNT = 1, EBDF = 0 (MAX = 0.25 × B1 + 6.80)	7.60	14.30	6.30	13.00	3.80	10.50	TBD	9.925	ns
B28b	CLKOUT falling edge to \overline{CS} negated GPCM write access TRLX = 0, CSNT = 1 ACS = 10 or ACS = 11, EBDF = 0 (MAX = 0.25 × B1 + 6.80)	_	14.30		13.00		10.50		9.925	ns
B28c	CLKOUT falling edge to $\overline{WE}(0:3)/BS_B[0:3]$ negated GPCM write access TRLX = 0, CSNT = 1 write access TRLX = 0, CSNT = 1, EBDF = 1 (MAX = 0.375 × B1 + 6.6)	10.90	18.00	10.90	18.00	5.20	12.30	TBD	11.28 2	ns
B28d	CLKOUT falling edge to \overline{CS} negated GPCM write access TRLX = 0, CSNT = 1, ACS = 10, or ACS = 11, EBDF = 1 (MAX = 0.375 × B1 + 6.6)	_	18.00	_	18.00		12.30	_	11.30	ns
B29	$\label{eq:weighted} \hline \hline WE(0:3)/BS_B[0:3] \mbox{ negated to } D(0:31) \\ \mbox{ High-Z GPCM write access, } CSNT = 0, \\ \mbox{ EBDF = 0 (MIN = } 0.25 \times B1 - 2.00) \\ \hline \hline \end{array}$	5.60		4.30		1.80		TBD		ns
B29a	$\label{eq:weighted} \hline \hline WE(0:3)/BS_B[0:3] \mbox{ negated to } D(0:31) \\ \mbox{ High-Z GPCM write access, TRLX = 0,} \\ \mbox{ CSNT = 1, EBDF = 0 (MIN = 0.50 \times B1 - 2.00) \\ \hline \end{array}$	13.20		10.50		5.60		4.25	_	ns
B29b	\overline{CS} negated to D(0:31) High Z GPCM write access, ACS = 00, TRLX = 0 & CSNT = 0 (MIN = 0.25 × B1 - 2.00)	5.60		4.30		1.80		1.125		ns
B29c	$\overline{\text{CS}}$ negated to D(0:31) High-Z GPCM write access, TRLX = 0, CSNT = 1, ACS = 10, or ACS = 11 EBDF = 0 (MIN = 0.50 × B1 - 2.00)	13.20		10.50		5.60	_	4.25	_	ns
B29d	$\label{eq:weighted} \hline \hline WE(0:3)/BS_B[0:3] \mbox{ negated to } D(0:31) \\ \mbox{ High-Z GPCM write access, TRLX = 1, } \\ \mbox{ CSNT = 1, EBDF = 0 (MIN = 1.50 \times B1 - 2.00) \\ \hline \hline \end{array}$	43.50		35.50		20.70		16.75	_	ns
B29e	$\overline{\text{CS}}$ negated to D(0:31) High-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10, or ACS = 11 EBDF = 0 (MIN = 1.50 × B1 - 2.00)	43.50		35.50		20.70		16.75		ns

Num	Characteristic	33	MHz	40 M	MHz	66 I	MHz	80 1	MHz	Unit
NUIII	Gilaracteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B29f	$\label{eq:weighted} \hline \hline WE(0:3/BS_B[0:3]) \mbox{ negated to } D(0:31) \\ \mbox{ High Z GPCM write access, TRLX = 0,} \\ \mbox{ CSNT = 1, EBDF = 1 (MIN = 0.375 \times B1 - 6.30) \\ \hline \hline \end{array}$	5.00		3.00		0.00		TBD	—	ns
B29g	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	5.00		3.00	_	0.00		TBD		ns
B29h	$\label{eq:weighted} \begin{array}{ c c } \hline WE(0:3)/BS_B[0:3] \mbox{ negated to } D(0:31) \\ \mbox{ High Z GPCM write access, } TRLX = 1, \\ \mbox{ CSNT = 1, } EBDF = 1 \mbox{ (MIN = } 0.375 \times B1 - 3.30) \\ \hline \end{array}$	38.40		31.10	_	17.50				ns
B29i	CS negated to D(0:31) (0:3) High-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1 (MIN = 0.375 × B1 - 3.30)	38.40		31.10		17.50		TBD		ns
B30	\overline{CS} , \overline{WE} (0:3)/BS_B[0:3] negated to A(0:31), BADDR(28:30) Invalid GPCM write access ⁷ (MIN = 0.25 × B1 - 2.00)	5.60		4.30	_	1.80		1.125	_	ns
B30a	$\label{eq:weighted_states} \begin{array}{ c c c c } \hline WE(0:3)/BS_B[0:3] \mbox{ negated to } A(0:31), \\ BADDR(28:30) \mbox{ Invalid GPCM, write} \\ access, TRLX = 0, CSNT = 1, \overline{CS} \mbox{ negated to } A(0:31) \mbox{ invalid GPCM write } access \\ TRLX = 0, CSNT = 1 \mbox{ ACS } = 10, \mbox{ or } ACS = = \\ 11, EBDF = 0 \mbox{ (MIN } = 0.50 \times B1 - 2.00) \end{array}$	13.20	_	10.50	_	5.60	_	4.25		ns
B30b	$eq:weighted_$	43.50		35.50		20.70		16.75		ns
B30c	$\label{eq:weighted} \hline \hline WE(0:3)/BS_B[0:3] \mbox{ negated to } A(0:31), \\ \mbox{BADDR}(28:30) \mbox{ invalid GPCM write} \\ \mbox{access, TRLX} = 0, \mbox{ CSNT} = 1. \mbox{ CS negated} \\ \mbox{to } A(0:31) \mbox{ invalid GPCM write access,} \\ \mbox{TRLX} = 0, \mbox{ CSNT} = 1 \mbox{ ACS} = 10, \mbox{ ACS} = = \\ \mbox{11, EBDF} = 1 \mbox{ (MIN} = 0.375 \times \mbox{ B1} - 3.00) \\ \hline \hline \hline \end{tabular}$	8.40		6.40		2.70		1.70		ns
B30d	$\label{eq:weighted} \hline WE(0:3)/BS_B[0:3] \mbox{ negated to } A(0:31), \\ BADDR(28:30) \mbox{ invalid GPCM write access } \\ TRLX = 1, \mbox{ CSNT = 1, } \hline CS \mbox{ negated to } \\ A(0:31) \mbox{ invalid GPCM write access } TRLX \\ = 1, \mbox{ CSNT = 1, } ACS = 10 \mbox{ or } 11, \mbox{ EBDF = 1 } \\ \hline \end{array}$	38.67		31.38	—	17.83		TBD		ns
B31	CLKOUT falling edge to $\overline{\text{CS}}$ valid - as requested by control bit CST4 in the corresponding word in the UPM (MAX = $0.00 \times \text{B1} + 6.00$)	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns

Niuma	Characteristic	33	MHz	40 I	MHz	66	MHz	80	MHz	Unit
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
B31a	CLKOUT falling edge to $\overline{\text{CS}}$ valid - as requested by control bit CST1 in the corresponding word in the UPM (MAX = $0.25 \times \text{B1} + 6.80$)	7.60	14.30	6.30	13.00	3.80	10.50	TBD	10.00	ns
B31b	CLKOUT rising edge to $\overline{\text{CS}}$ valid - as requested by control bit CST2 in the corresponding word in the UPM (MAX = $0.00 \times \text{B1} + 8.00$)	1.50	8.00	1.50	8.00	1.50	8.00	1.50	8.00	ns
B31c	CLKOUT rising edge to $\overline{\text{CS}}$ valid- as requested by control bit CST3 in the corresponding word in the UPM (MAX = $0.25 \times \text{B1} + 6.30$)	7.60	13.80	6.30	12.50	3.80	10.00	TBD	9.40	ns
B31d	CLKOUT falling edge to \overline{CS} valid, as requested by control bit CST1 in the corresponding word in the UPM EBDF = 1 (MAX = 0.375 × B1 + 6.6)	13.30	18.00	11.30	16.00	7.60	12.30	TBD	11.30	ns
B32	CLKOUT falling edge to $\overline{\text{BS}}$ valid- as requested by control bit BST4 in the corresponding word in the UPM (MAX = $0.00 \times \text{B1} + 6.00$)	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B32a	CLKOUT falling edge to $\overline{\text{BS}}$ valid - as requested by control bit BST1 in the corresponding word in the UPM, EBDF = 0 (MAX = 0.25 × B1 + 6.80)	7.60	14.30	6.30	13.00	3.80	10.50	TBD	10.00	ns
B32b	CLKOUT rising edge to $\overline{\text{BS}}$ valid - as requested by control bit BST2 in the corresponding word in the UPM (MAX = $0.00 \times \text{B1} + 8.00$)	1.50	8.00	1.50	8.00	1.50	8.00	1.50	8.00	ns
B32c	CLKOUT rising edge to $\overline{\text{BS}}$ valid - as requested by control bit BST3 in the corresponding word in the UPM (MAX = $0.25 \times \text{B1} + 6.80$)	7.60	14.30	6.30	13.00	3.80	10.50	TBD	10.00	ns
B32d	CLKOUT falling edge to $\overline{\text{BS}}$ valid- as requested by control bit BST1 in the corresponding word in the UPM, EBDF = 1 (MAX = 0.375 × B1 + 6.60)	13.30	18.00	11.30	16.00	7.60	12.30	TBD	11.30	ns
B33	CLKOUT falling edge to $\overline{\text{GPL}}$ valid - as requested by control bit GxT4 in the corresponding word in the UPM (MAX = $0.00 \times \text{B1} + 6.00$)	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B33a	CLKOUT rising edge to $\overline{\text{GPL}}$ valid - as requested by control bit GxT3 in the corresponding word in the UPM (MAX = $0.25 \times \text{B1} + 6.80$)	7.60	14.30	6.30	13.00	3.80	10.50	TBD	10.00	ns

Num	Characteristic	33 I	MHz	40	MHz	66	MHz	80	MHz	11:5:4
Num	Characteristic	Min	Max	Min	Мах	Min	Max	Min	Max	Unit
B34	A(0:31), BADDR(28:30), and D(0:31) to \overline{CS} valid - as requested by control bit CST4 in the corresponding word in the UPM (MIN = 0.25 × B1 - 2.00)	5.60		4.30		1.80		1.125		ns
B34a	A(0:31), BADDR(28:30), and D(0:31) to \overline{CS} valid - as requested by control bit CST1 in the corresponding word in the UPM (MIN = $0.50 \times B1 - 2.00$)	13.20		10.50		5.60		4.25		ns
B34b	A(0:31), BADDR(28:30), and D(0:31) to \overline{CS} valid - as requested by CST2 in the corresponding word in UPM (MIN = $0.75 \times B1 - 2.00$)	20.70		16.70	_	9.40		6.80		ns
B35	A(0:31), BADDR(28:30) to $\overline{\text{CS}}$ valid - as requested by control bit BST4 in the corresponding word in the UPM (MIN = $0.25 \times \text{B1} - 2.00$)	5.60		4.30	_	1.80		1.125		ns
B35a	A(0:31), BADDR(28:30), and D(0:31) to \overline{BS} valid - As requested by BST1 in the corresponding word in the UPM (MIN = 0.50 × B1 - 2.00)	13.20		10.50		5.60		4.25		ns
B35b	A(0:31), BADDR(28:30), and D(0:31) to BS valid - as requested by control bit BST2 in the corresponding word in the UPM (MIN = $0.75 \times B1 - 2.00$)	20.70		16.70	_	9.40		7.40		ns
B36	A(0:31), BADDR(28:30), and D(0:31) to \overline{GPL} valid as requested by control bit GxT4 in the corresponding word in the UPM (MIN = 0.25 × B1 - 2.00)	5.60		4.30	_	1.80		1.125		ns
B37	UPWAIT valid to CLKOUT falling edge 8 (MIN = 0.00 × B1 + 6.00)	6.00	_	6.00	_	6.00	_	6.00		ns
B38	CLKOUT falling edge to UPWAIT valid ⁸ (MIN = $0.00 \times B1 + 1.00$)	1.00		1.00	_	1.00	_	1.00	_	ns
B39	$\overline{\text{AS}}$ valid to CLKOUT rising edge ⁹ (MIN = 0.00 × B1 + 7.00)	7.00		7.00		7.00	—	7.00	_	ns
B40	A(0:31), TSIZ(0:1), RD/WR, $\overline{\text{BURST}}$, valid to CLKOUT rising edge (MIN = $0.00 \times \text{B1}$ + 7.00)	7.00		7.00	_	7.00	_	7.00	_	ns
B41	$\overline{\text{TS}}$ valid to CLKOUT rising edge (setup time) (MIN = 0.00 × B1 + 7.00)	7.00		7.00		7.00	_	7.00		ns
B42	CLKOUT rising edge to $\overline{\text{TS}}$ valid (hold time) (MIN = 0.00 × B1 + 2.00)	2.00	_	2.00	_	2.00	_	2.00	_	ns
B43	$\overline{\text{AS}}$ negation to memory controller signals negation (MAX = TBD)	-	TBD	_	TBD	_	TBD	_	TBD	ns

- ¹ For part speeds above 50 MHz, use 9.80 ns for B11a.
- ² The timing required for BR input is relevant when the MPC875/870 is selected to work with the internal bus arbiter. The timing for BG input is relevant when the MPC875/870 is selected to work with the external bus arbiter.
- ³ For part speeds above 50 MHz, use 2 ns for B17.
- ⁴ The D(0:31) input timings B18 and B19 refer to the rising edge of the CLKOUT in which the TA input signal is asserted.
- ⁵ For part speeds above 50 MHz, use 2 ns for B19.
- ⁶ The D(0:31) input timings B20 and B21 refer to the falling edge of the CLKOUT. This timing is valid only for read accesses controlled by chip-selects under control of the user-programmable machine (UPM) in the memory controller, for data beats where DLT3 = 1 in the RAM words. (This is only the case where data is latched on the falling edge of CLKOUT.)
- ⁷ The timing B30 refers to \overline{CS} when ACS = 00 and to $\overline{WE}(0:3)$ when CSNT = 0.
- ⁸ The signal UPWAIT is considered asynchronous to the CLKOUT and synchronized internally. The timings specified in B37 and B38 are specified to enable the freeze of the UPM output signals as described in Figure 19.
- ⁹ The AS signal is considered asynchronous to the CLKOUT. The timing B39 is specified in order to allow the behavior specified in Figure 22.

Figure 4 is the control timing diagram.

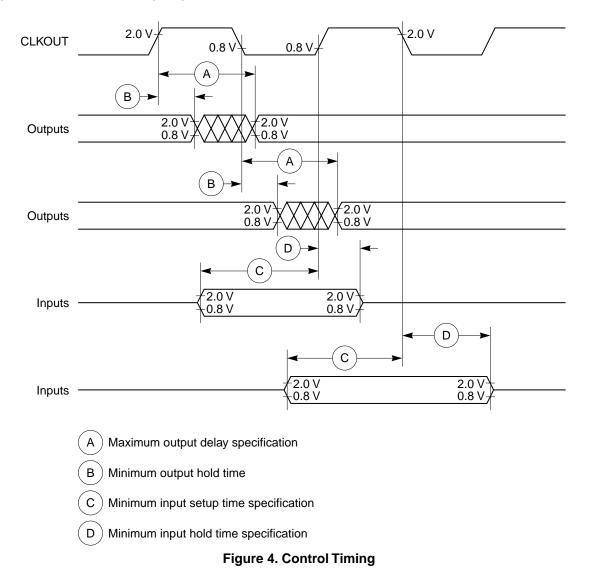


Figure 5 provides the timing for the external clock.

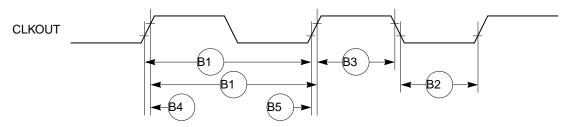


Figure 5. External Clock Timing

Figure 6 provides the timing for the synchronous output signals.

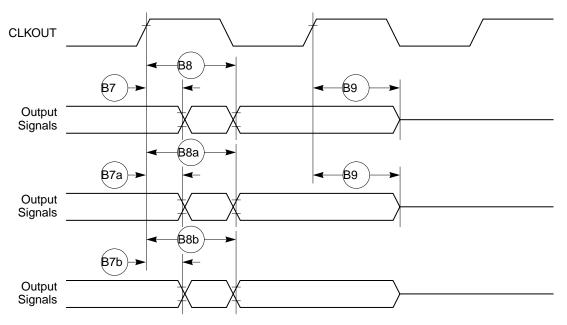


Figure 6. Synchronous Output Signals Timing

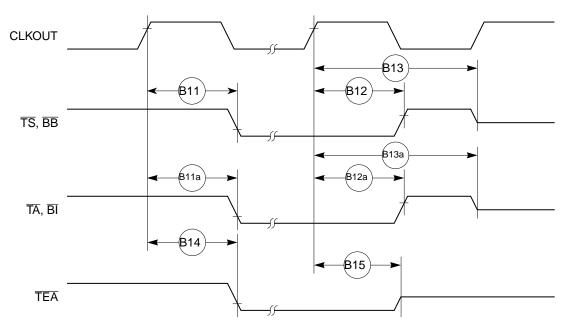


Figure 7 provides the timing for the synchronous active pull-up and open-drain output signals.



Figure 8 provides the timing for the synchronous input signals.

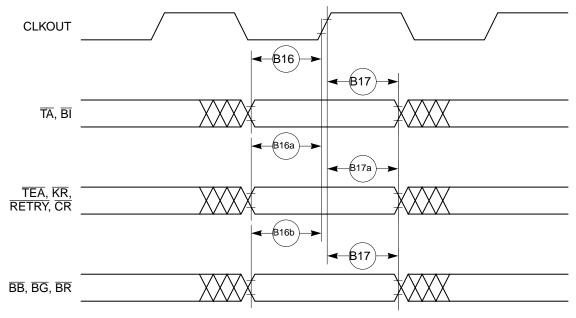


Figure 8. Synchronous Input Signals Timing

Figure 9 provides normal case timing for input data. It also applies to normal read accesses under the control of the user-programmable machine (UPM) in the memory controller.

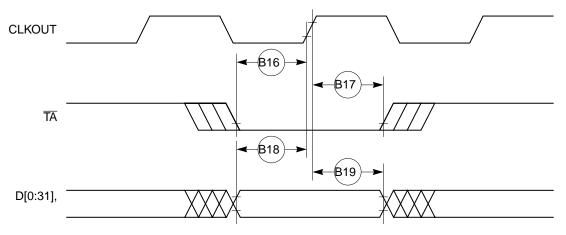


Figure 9. Input Data Timing in Normal Case

Figure 10 provides the timing for the input data controlled by the UPM for data beats where DLT3 = 1 in the UPM RAM words. (This is only the case where data is latched on the falling edge of CLKOUT.)

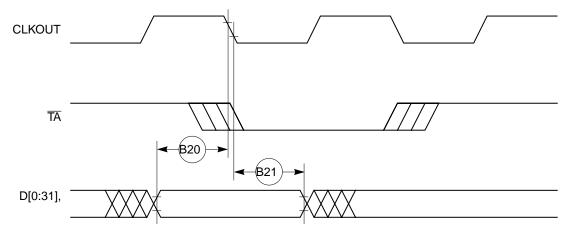


Figure 10. Input Data Timing when Controlled by UPM in the Memory Controller and DLT3 = 1

Figure 11 through Figure 14 provide the timing for the external bus read controlled by various GPCM factors.

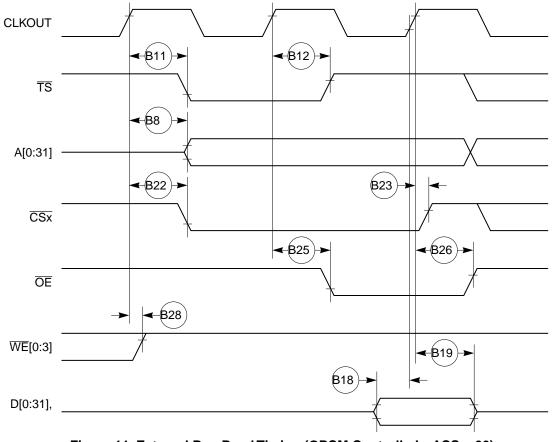
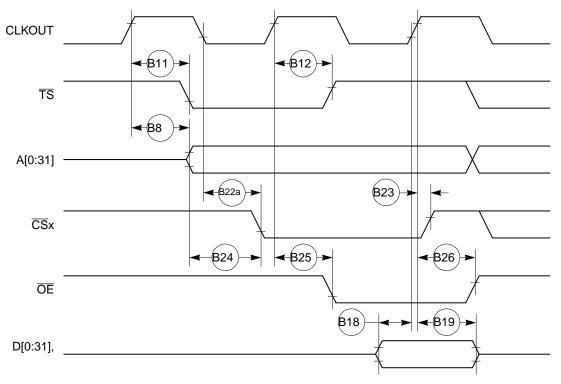


Figure 11. External Bus Read Timing (GPCM Controlled—ACS = 00)





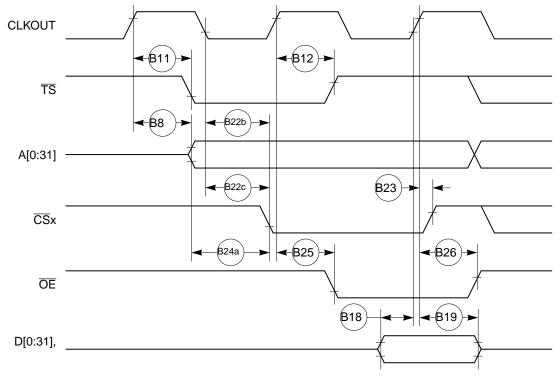


Figure 13. External Bus Read Timing (GPCM Controlled—TRLX = 0, ACS = 11)

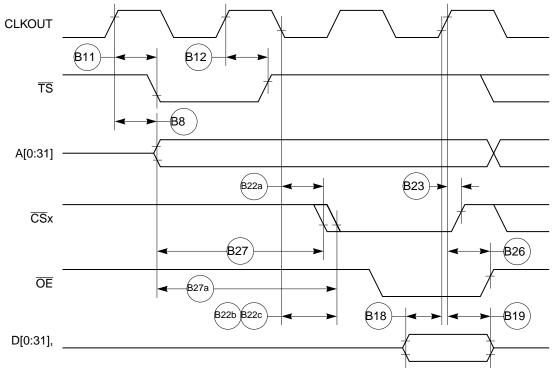


Figure 14. External Bus Read Timing (GPCM Controlled—TRLX = 1, ACS = 10, ACS = 11)

Figure 15 through Figure 17 provide the timing for the external bus write controlled by various GPCM factors.

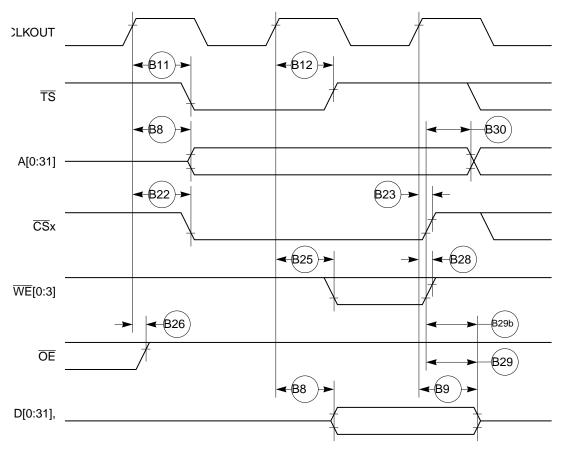


Figure 15. External Bus Write Timing (GPCM Controlled—TRLX = 0, CSNT = 0)

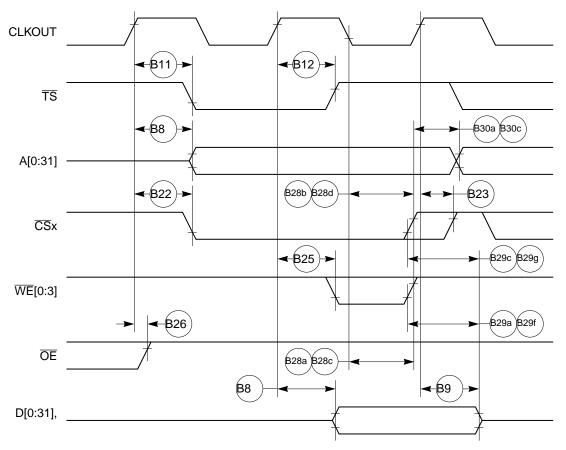


Figure 16. External Bus Write Timing (GPCM Controlled—TRLX = 0, CSNT = 1)

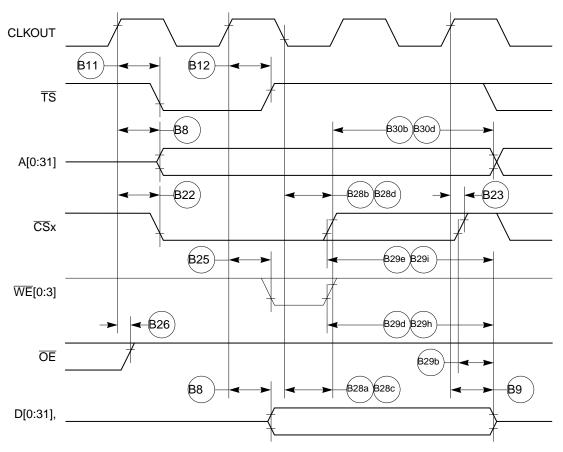


Figure 17. External Bus Write Timing (GPCM Controlled—TRLX = 1, CSNT = 1)

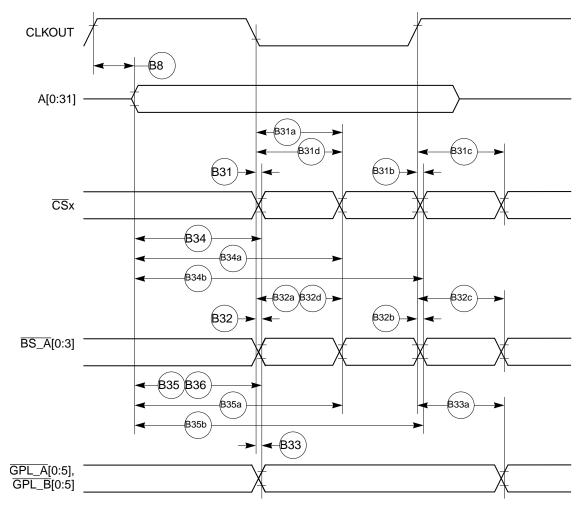


Figure 18 provides the timing for the external bus controlled by the UPM.

Figure 18. External Bus Timing (UPM Controlled Signals)

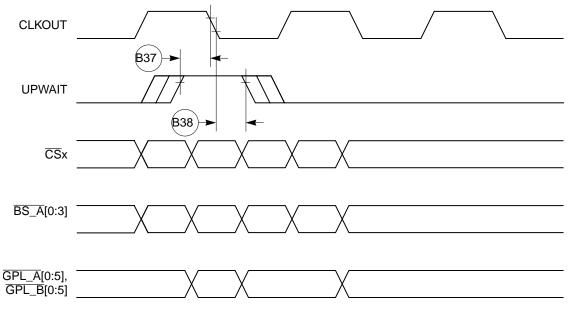


Figure 19 provides the timing for the asynchronous asserted UPWAIT signal controlled by the UPM.

Figure 19. Asynchronous UPWAIT Asserted Detection in UPM Handled Cycles Timing

Figure 20 provides the timing for the asynchronous negated UPWAIT signal controlled by the UPM.

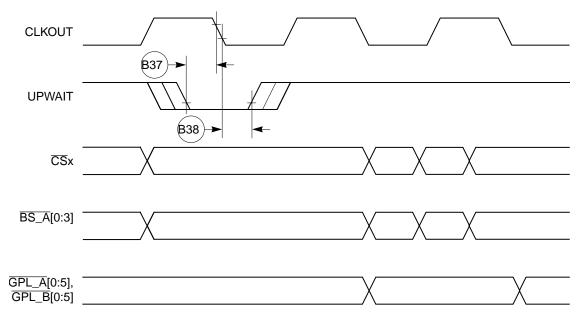


Figure 20. Asynchronous UPWAIT Negated Detection in UPM Handled Cycles Timing

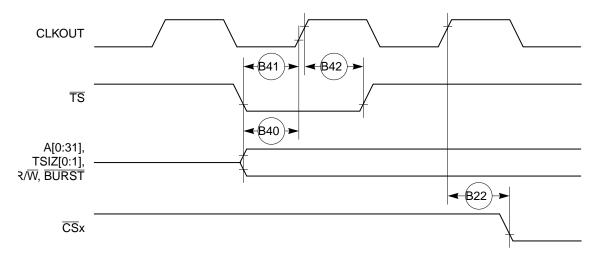


Figure 21 provides the timing for the synchronous external master access controlled by the GPCM.

Figure 21. Synchronous External Master Access Timing (GPCM Handled ACS = 00)

Figure 22 provides the timing for the asynchronous external master memory access controlled by the GPCM.

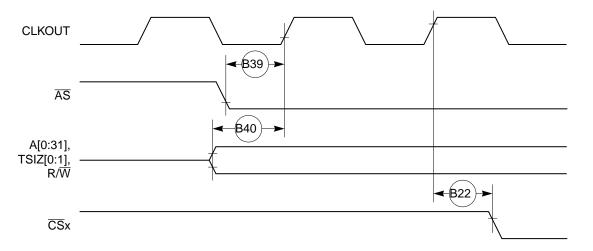




Figure 23 provides the timing for the asynchronous external master control signals negation.

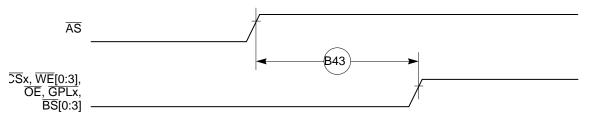


Figure 23. Asynchronous External Master—Control Signals Negation Timing

Table 11	provides	interrunt	timing	for the	MPC875/870.
	provides	menupi	unning	101 the	MI C075/070.

Table 11. Interrupt Timing

Num	Characteristic ¹	All Frequenc	ies	Unit
Num	Characteristic	Min	Max	
139	IRQx valid to CLKOUT rising edge (set up time)	6.00		ns
140	IRQx hold time after CLKOUT	2.00		ns
I41	IRQx pulse width low	3.00		ns
142	IRQx pulse width high	3.00		ns
143	IRQx edge-to-edge time	4xT _{CLOCKOUT}		

¹ The I39 and I40 timings describe the testing conditions under which the IRQ lines are tested when being defined as level sensitive. The IRQ lines are synchronized internally and do not have to be asserted or negated with reference to the CLKOUT.

The I41, I42, and I43 timings are specified to allow correct functioning of the \overline{IRQ} lines detection circuitry and have no direct relation with the total system interrupt latency that the MPC875/870 is able to support.

Figure 24 provides the interrupt detection timing for the external level-sensitive lines.

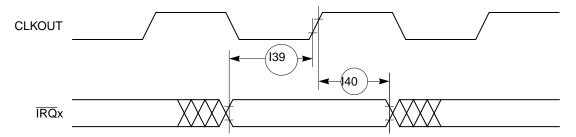


Figure 24. Interrupt Detection Timing for External Level Sensitive Lines

Figure 25 provides the interrupt detection timing for the external edge-sensitive lines.

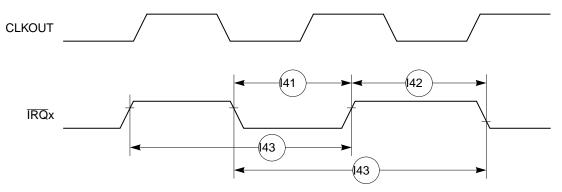


Figure 25. Interrupt Detection Timing for External Edge Sensitive Lines

Table 12. PCMCIA Timing

		33 MHz		40 I	40 MHz		66 MHz		80 MHz	
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	- Unit
P44	A(0:31), $\overline{\text{REG}}$ valid to PCMCIA strobe asserted ¹ (MIN = 0.75 × B1 - 2.00)	20.70	_	16.70		9.40		7.40		ns
P45	A(0:31), $\overline{\text{REG}}$ valid to ALE negation ¹ (MIN = 1.00 × B1 - 2.00)	28.30	_	23.00		13.20		10.50	_	ns
P46	CLKOUT to $\overline{\text{REG}}$ valid (MAX = 0.25 × B1 + 8.00)	7.60	15.60	6.30	14.30	3.80	11.80	TBD	11.125	ns
P47	CLKOUT to $\overline{\text{REG}}$ Invalid (MIN = 0.25 × B1 + 1.00)	8.60	—	7.30	_	4.80	_	4.125	—	ns
P48	CLKOUT to $\overline{CE1}$, $\overline{CE2}$ asserted. (MAX = 0.25 × B1 + 8.00)	7.60	15.60	6.30	14.30	3.80	11.80	TBD	11.125	ns
P49	CLKOUT to $\overline{CE1}$, $\overline{CE2}$ negated. (MAX = 0.25 × B1 + 8.00)	7.60	15.60	6.30	14.30	3.80	11.80	TBD	11.125	ns
P50	CLKOUT to \overrightarrow{PCOE} , \overrightarrow{IORD} , \overrightarrow{PCWE} , \overrightarrow{IOWR} assert time. (MAX = 0.00 × B1 + 11.00)	_	11.00	_	11.00	_	11.00	_	11.00	ns
P51	CLKOUT to \overrightarrow{PCOE} , \overrightarrow{IORD} , \overrightarrow{PCWE} , \overrightarrow{IOWR} negate time. (MAX = 0.00 × B1 + 11.00)	2.00	11.00	2.00	11.00	2.00	11.00	2.00	11.00	ns
P52	CLKOUT to ALE assert time (MAX = 0.25 × B1 + 6.30)	7.60	13.80	6.30	12.50	3.80	10.00	TBD	9.40	ns
P53	CLKOUT to ALE negate time (MAX = 0.25 × B1 + 8.00)		15.60		14.30		11.80	_	11.125	ns
P54	PCWE, IOWR negated to D(0:31) invalid. ¹ (MIN = $0.25 \times$ B1 - 2.00)	5.60	—	4.30	_	1.80		1.125	_	ns
P55	WAITA and WAITB valid toCLKOUT rising edge.1(MIN = $0.00 \times B1 + 8.00$)	8.00	_	8.00		8.00		8.00	_	ns
P56	CLKOUT rising edge to \overline{WAITA} and \overline{WAITB} invalid. ¹ (MIN = 0.00 × B1 + 2.00)	2.00	-	2.00	_	2.00		2.00	_	ns

¹ PSST = 1. Otherwise add PSST times cycle time.

PSHT = 0. Otherwise add PSHT times cycle time.

These synchronous timings define when the \overline{WAITA} signals are detected in order to freeze (or relieve) the PCMCIA current cycle. The \overline{WAITA} assertion will be effective only if it is detected 2 cycles before the PSL timer expiration. See the PCMCIA Interface in the *MPC885 PowerQUICC User s Manual*.

Figure 26 provides the PCMCIA access cycle timing for the external bus read.

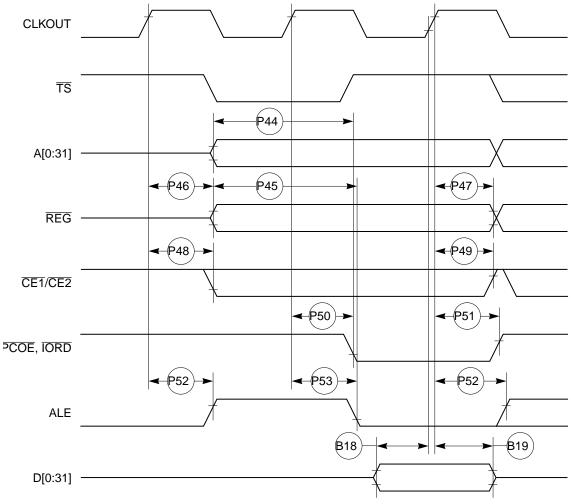


Figure 26. PCMCIA Access Cycles Timing External Bus Read

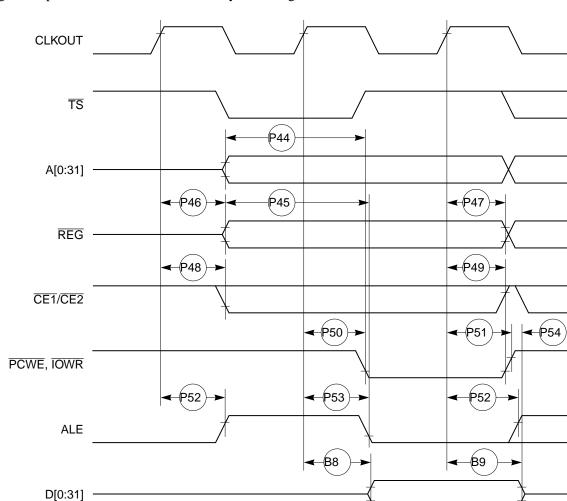


Figure 27 provides the PCMCIA access cycle timing for the external bus write.



Figure 28 provides the PCMCIA \overline{WAIT} signals detection timing.

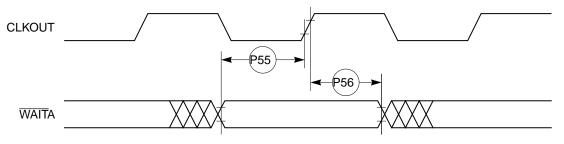


Figure 28. PCMCIA WAIT Signals Detection Timing

Table 13 shows the PCMCIA port timing for the MPC875/870.

Table 1	3. PCM	CIA Po	rt Timing
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Num	Characteristic		33 MHz		40 MHz		66 MHz		80 MHz	
Num	Characteristic	Min	Min Max Min	Max	Min	Max	Min	Max	Unit	
P57	CLKOUT to OPx Valid (MAX = $0.00 \times B1$ + 19.00)		19.00	_	19.00	_	19.00	_	TBD	ns
P58	HRESET negated to OPx drive 1 (MIN = 0.75 × B1 + 3.00)	25.70	_	21.70	_	14.40	_	12.40	_	ns
P59	IP_Xx valid to CLKOUT rising edge (MIN = $0.00 \times B1 + 5.00$)	5.00	_	5.00	_	5.00	_	5.00	—	ns
P60	CLKOUT rising edge to IP_Xx invalid (MIN = $0.00 \times B1 + 1.00$)	1.00	_	1.00	_	1.00		1.00	_	ns

¹ OP2 and OP3 only

Figure 29 provides the PCMCIA output port timing for the MPC875/870.

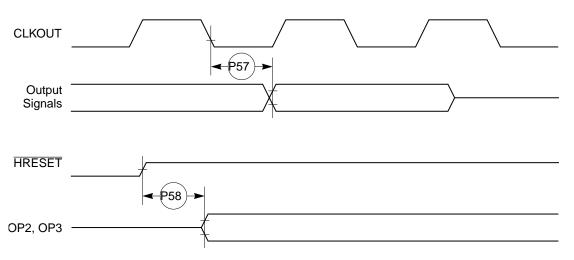


Figure 29. PCMCIA Output Port Timing

Figure 30 provides the PCMCIA output port timing for the MPC875/870.

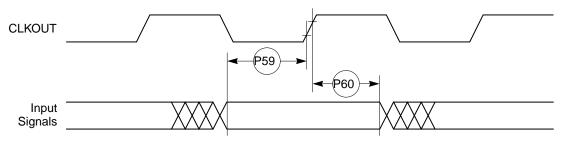


Figure 30. PCMCIA Input Port Timing

Table 14 shows the debug port timing for the MPC875/870.

Table 14. Debug Port Timing

Num	Characteristic	All Frequencie	11	
	Characteristic	Min	Max	Unit
D61	DSCK cycle time	3xT _{CLOCKOUT}		_
D62	DSCK clock pulse width	1.25xT _{CLOCKOUT}		_
D63	DSCK rise and fall times	0.00	3.00	ns
D64	DSDI input data setup time	8.00		ns
D65	DSDI data hold time	5.00		ns
D66	DSCK low to DSDO data valid	0.00	15.00	ns
D67	DSCK low to DSDO invalid	0.00	2.00	ns

Figure 31 provides the input timing for the debug port clock.

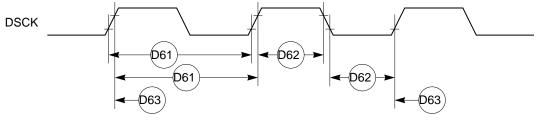


Figure 31. Debug Port Clock Input Timing

Figure 32 provides the timing for the debug port.

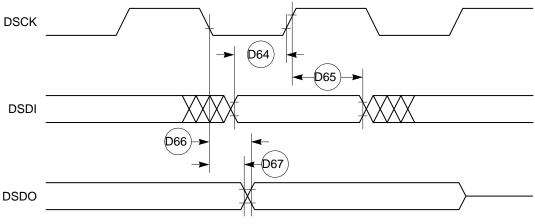


Figure 32. Debug Port Timings

Table 15 shows the reset timing for the MPC875/870.

Table 15. Reset Timing

NI	Ohenneterietie	33	MHz	40 1	MHz	66 I	MHz	80 MHz		
Num	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	Unit
R69	CLKOUT to $\overrightarrow{\text{HRESET}}$ high impedance (MAX = 0.00 × B1 + 20.00)		20.00	_	20.00	_	20.00	-	20.00	ns
R70	CLKOUT to SRESET high impedance (MAX = $0.00 \times$ B1 + 20.00)	_	20.00	_	20.00	_	20.00	-	20.00	ns
R71	$\frac{\text{RSTCONF}}{(\text{MIN} = 17.00 \times \text{B1})}$	515.20	_	425.00	_	257.60	_	212.50	_	ns
R72	—	_	_	_	_	_	_	_	_	_
R73	Configuration data to HRESET rising edge set up time (MIN = $15.00 \times B1 + 50.00$)	504.50	_	425.00	_	277.30	_	237.50		ns
R74	Configuration data to RSTCONF rising edge set up time (MIN = $0.00 \times B1 + 350.00$)	350.00	_	350.00	_	350.00	_	350.00		ns
R75	Configuration data hold time after $\overrightarrow{\text{RSTCONF}}$ negation (MIN = 0.00 × B1 + 0.00)	0.00		0.00		0.00	_	0.00		ns
R76	Configuration data hold time after $\overrightarrow{\text{HRESET}}$ negation (MIN = 0.00 × B1 + 0.00)	0.00		0.00		0.00		0.00		ns
R77	HRESET and RSTCONF asserted to data out drive (MAX = $0.00 \times B1 + 25.00$)		25.00		25.00		25.00	_	25.00	ns
R78	$\frac{\text{RSTCONF}}{\text{RSTCONF}} \text{ negated to data} \\ \text{out high impedance. (MAX} \\ = 0.00 \times \text{B1} + 25.00)$		25.00	_	25.00	_	25.00	-	25.00	ns
R79	CLKOUT of last rising edge before chip three-states HRESET to data out high impedance. (MAX = $0.00 \times$ B1 + 25.00)		25.00		25.00	_	25.00	_	25.00	ns
R80	DSDI, DSCK set up (MIN = 3.00 × B1)	90.90		75.00		45.50		37.50		ns

Num	Characteristic	33 MHz		40 MHz		66 MHz		80 MHz		Unit
	Characteristic	Min	Max	Min	Max	Min	Max	Min	Max	
R81	DSDI, DSCK hold time (MIN = $0.00 \times B1 + 0.00$)	0.00	_	0.00	_	0.00	_	0.00	_	ns
R82	SRESET negated to CLKOUT rising edge for DSDI and DSCK sample (MIN = $8.00 \times B1$)	242.40		200.00		121.20	_	100.00	_	ns

Table 15. Reset Timing (continued)

Figure 33 shows the reset timing for the data bus configuration.

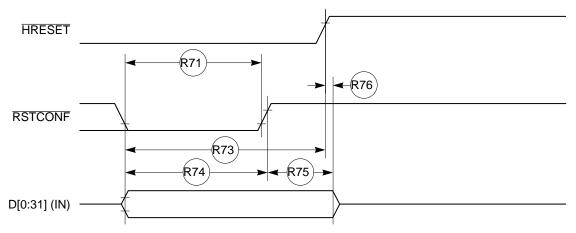


Figure 33. Reset Timing—Configuration from Data Bus

Figure 34 provides the reset timing for the data bus weak drive during configuration.

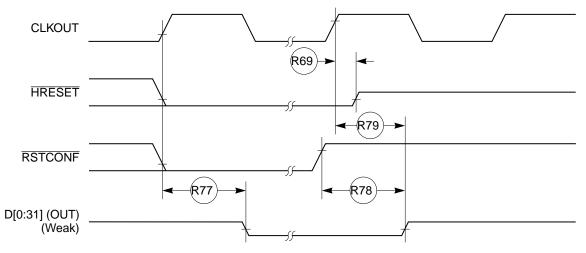


Figure 34. Reset Timing—Data Bus Weak Drive during Configuration

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Figure 35 provides the reset timing for the debug port configuration.

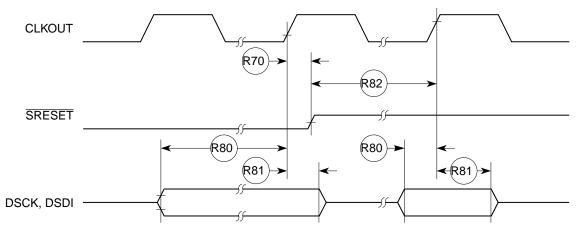


Figure 35. Reset Timing—Debug Port Configuration

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Table 16 provides the JTAG timings for the MPC875/870 shown in Figure 36 to Figure 39.

Table 16. JTAG Timing

Num	Characteristic	A Freque		Unit
		Min	Max	
J82	TCK cycle time	100.00	_	ns
J83	TCK clock pulse width measured at 1.5 V	40.00	_	ns
J84	TCK rise and fall times	0.00	10.00	ns
J85	TMS, TDI data setup time	5.00	_	ns
J86	TMS, TDI data hold time	25.00	_	ns
J87	TCK low to TDO data valid	—	27.00	ns
J88	TCK low to TDO data invalid	0.00	_	ns
J89	TCK low to TDO high impedance	—	20.00	ns
J90	TRST assert time	100.00	_	ns
J91	TRST setup time to TCK low	40.00	_	ns
J92	TCK falling edge to output valid	—	50.00	ns
J93	TCK falling edge to output valid out of high impedance	—	50.00	ns
J94	TCK falling edge to output high impedance	_	50.00	ns
J95	Boundary scan input valid to TCK rising edge	50.00	_	ns
J96	TCK rising edge to boundary scan input invalid	50.00		ns

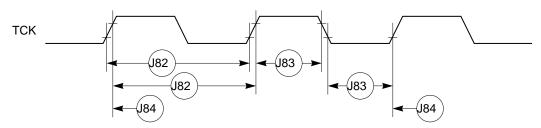


Figure 36. JTAG Test Clock Input Timing

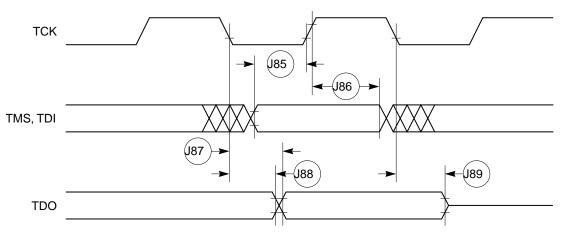


Figure 37. JTAG Test Access Port Timing Diagram

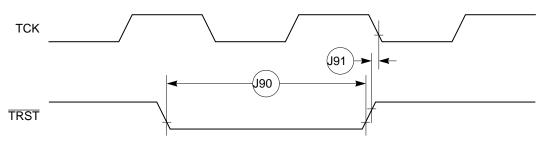


Figure 38. JTAG TRST Timing Diagram

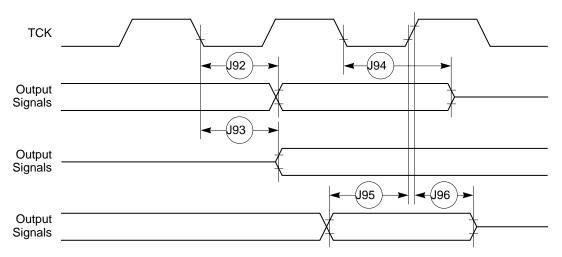


Figure 39. Boundary Scan (JTAG) Timing Diagram

13 CPM Electrical Characteristics

This section provides the AC and DC electrical specifications for the communications processor module (CPM) of the MPC875/870.

13.1 Port C Interrupt AC Electrical Specifications

Table 17 provides the timings for port C interrupts.

Num	Characteristic	33.34	MHz	Unit
Num	Characteristic	Min	Max	
35	Port C interrupt pulse width low (edge-triggered mode)	55	_	ns
36	Port C interrupt minimum time between active edges	55	_	ns

Figure 40 shows the port C interrupt detection timing.

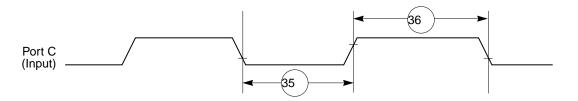


Figure 40. Port C Interrupt Detection Timing

13.2 IDMA Controller AC Electrical Specifications

Table 18 provides the IDMA controller timings as shown in Figure 41 to Figure 44.

Num	Characteristic	A Frequ	Unit	
		Min	Max	
40	DREQ setup time to clock high	7	_	ns
41	DREQ hold time from clock high	3	_	ns
42	SDACK assertion delay from clock high	_	12	ns
43	SDACK negation delay from clock low	_	12	ns
44	SDACK negation delay from TA low	_	20	ns
45	SDACK negation delay from clock high	_	15	ns
46	TA assertion to falling edge of the clock setup time (applies to external TA)	7	_	ns

Table 18. IDMA Controller Timing

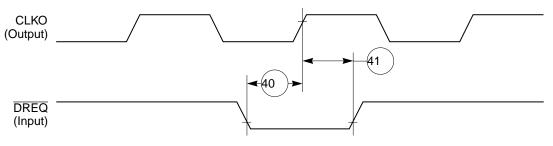
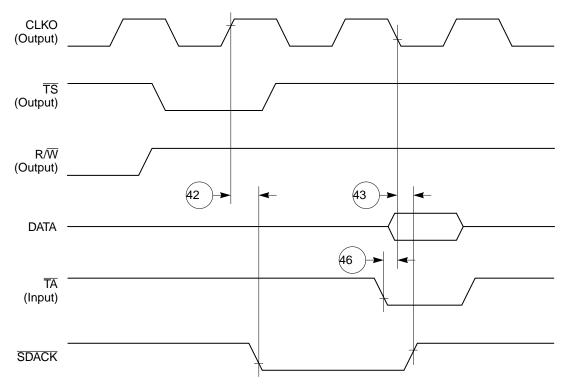


Figure 41. IDMA External Requests Timing Diagram





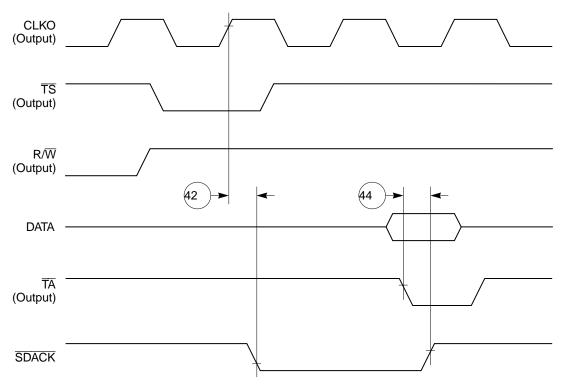


Figure 43. SDACK Timing Diagram—Peripheral Write, Internally-Generated TA

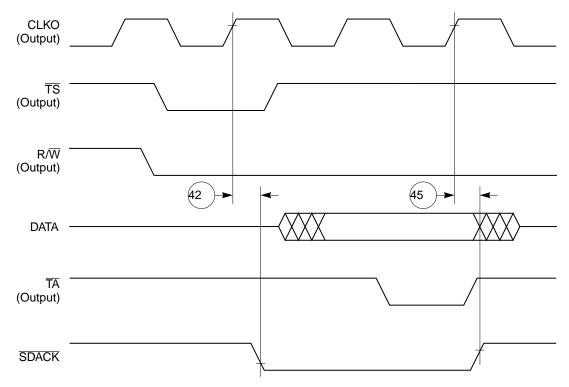


Figure 44. SDACK Timing Diagram—Peripheral Read, Internally-Generated TA

13.3 Baud Rate Generator AC Electrical Specifications

Table 19 provides the baud rate generator timings as shown in Figure 45.

Table 19. Baud Rate Generator Timing

Num	Characteristic	A Freque		Unit
		Min Max		
50	BRGO rise and fall time		10	ns
51	BRGO duty cycle	40	60	%
52	BRGO cycle	40	_	ns

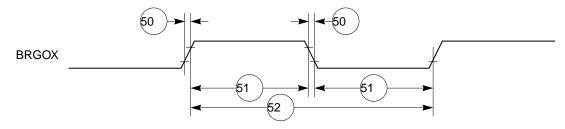


Figure 45. Baud Rate Generator Timing Diagram

13.4 Timer AC Electrical Specifications

Table 20 provides the general-purpose timer timings as shown in Figure 46.

Table 20. Timer Timin	g
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Num	Characteristic	All Frequencies		Unit
	Min		Max	
61	TIN/TGATE rise and fall time	10		ns
62	TIN/TGATE low time	1		clk
63	TIN/TGATE high time	2		clk
64	TIN/TGATE cycle time	3	_	clk
65	CLKO low to TOUT valid	3	25	ns

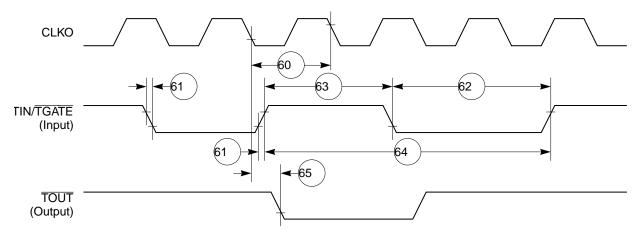


Figure 46. CPM General-Purpose Timers Timing Diagram

13.5 Serial Interface AC Electrical Specifications

Table 21 provides the serial interface timings as shown in Figure 47 to Figure 51.

Table 21. SI Timing

Num	Characteristic	All Freq	Unit	
Num	Characteristic	Min Max		Onit
70	L1RCLKB, L1TCLKB frequency (DSC = 0) $^{1, 2}$	—	SYNCCLK /2.5	MHz
71	L1RCLKB, L1TCLKB width low (DSC = 0) 2	P + 10	_	ns
71a	L1RCLKB, L1TCLKB width high (DSC = 0) 3	P + 10	—	ns
72	L1TXDB, L1ST(1–2), L1RQ, L1CLKO rise/fall time		15.00	ns
73	L1RSYNCB, L1TSYNCB valid to L1CLKB edge (SYNC setup time)	20.00		ns
74	L1CLKB edge to L1RSYNCB, L1TSYNCB, invalid (SYNC hold time)	35.00		ns

		All Frequencies		
Num	Characteristic	Min	Max	Unit
75	L1RSYNCB, L1TSYNCB rise/fall time		15.00	ns
76	L1RXDB valid to L1CLKB edge (L1RXDB setup time)	17.00	_	ns
77	L1CLKB edge to L1RXDB invalid (L1RXDB hold time)	13.00	—	ns
78	L1CLKB edge to L1ST(1-2) valid ⁴	10.00	45.00	ns
78A	L1SYNCB valid to L1ST(1-2) valid	10.00	45.00	ns
79	L1CLKB edge to L1ST(1-2) invalid	10.00	45.00	ns
80	L1CLKB edge to L1TXDB valid	10.00	55.00	ns
80A	L1TSYNCB valid to L1TXDB valid ⁴	10.00	55.00	ns
81	L1CLKB edge to L1TXDB high impedance	0.00	42.00	ns
82	L1RCLKB, L1TCLKB frequency (DSC =1)	_	16.00 or SYNCCLK /2	MHz
83	L1RCLKB, L1TCLKB width low (DSC =1)	P + 10	—	ns
83a	L1RCLKB, L1TCLKB width high $(DSC = 1)^3$	P + 10	—	ns
84	L1CLKB edge to L1CLKOB valid (DSC = 1)	_	30.00	ns
85	L1RQB valid before falling edge of L1TSYNCB ⁴	1.00	—	L1TCLK
86	L1GRB setup time ²	42.00	—	ns
87	L1GRB hold time	42.00	—	ns
88	L1CLKB edge to L1SYNCB valid (FSD = 00) CNT = 0000, BYT = 0, DSC = 0)		0.00	ns

Table 21. SI Timing (continued)

¹ The ratio SyncCLK/L1RCLKB must be greater than 2.5/1.

² These specs are valid for IDL mode only.

³ Where P = 1/CLKOUT. Thus for a 25-MHz CLKO1 rate, P = 40 ns.

⁴ These strobes and TxD on the first bit of the frame become valid after the L1CLKB edge or L1SYNCB, whichever comes later.

CPM Electrical Characteristics

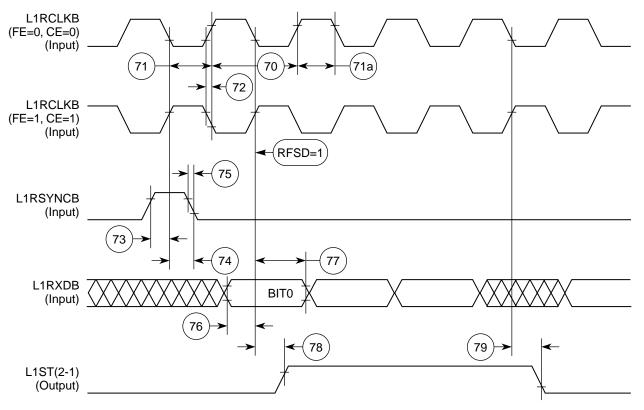
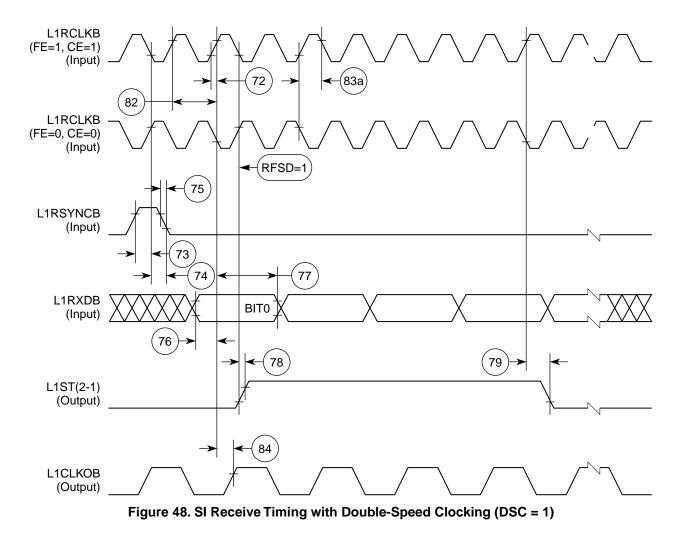
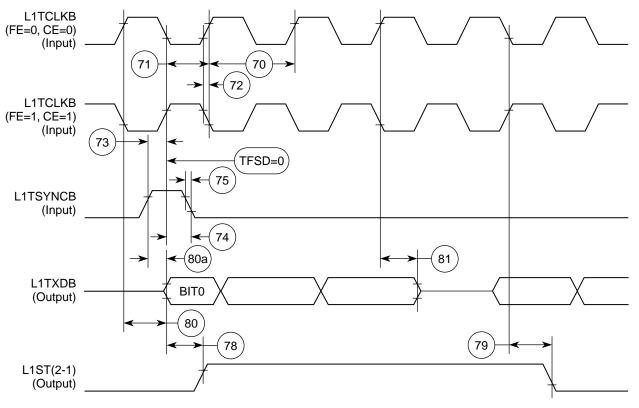


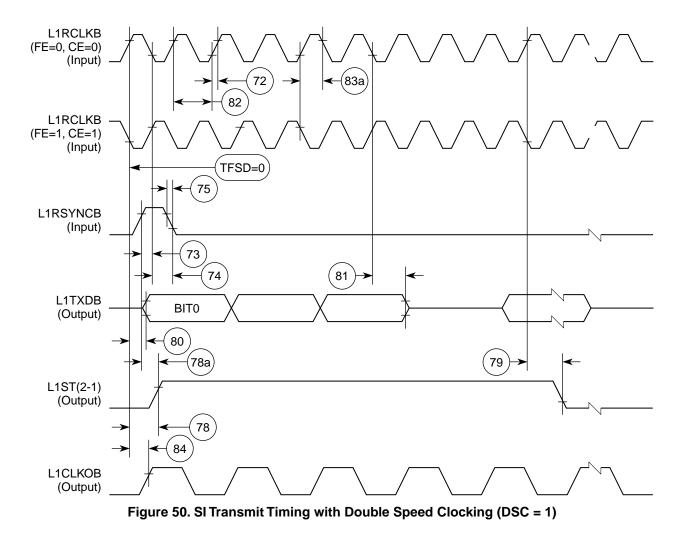
Figure 47. SI Receive Timing Diagram with Normal Clocking (DSC = 0)

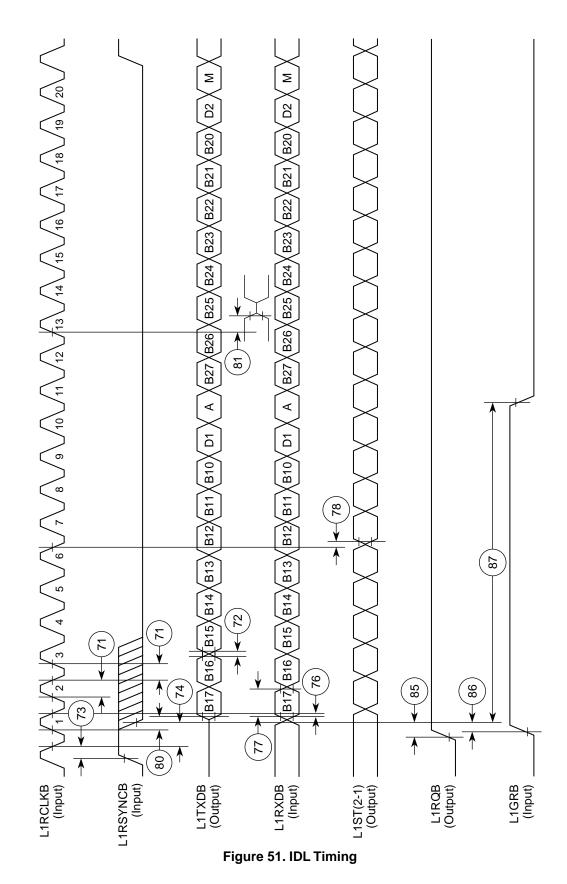


CPM Electrical Characteristics









13.6 SCC in NMSI Mode Electrical Specifications

Table 22 provides the NMSI external clock timing.

Num	Characteristic	All Frequencies		All Frequencies		— Unit
Num	Characteristic	Min	Max	Unit		
100	RCLK3 and TCLK3 width high ¹	1/SYNCCLK		ns		
101	RCLK3 and TCLK3 width low	1/SYNCCLK +5	_	ns		
102	RCLK3 and TCLK3 rise/fall time	—	15.00	ns		
103	TXD3 active delay (from TCLK3 falling edge)	0.00	50.00	ns		
104	RTS3 active/inactive delay (from TCLK3 falling edge)	0.00	50.00	ns		
105	CTS3 setup time to TCLK3 rising edge	5.00	_	ns		
106	RXD3 setup time to RCLK3 rising edge	5.00	_	ns		
107	RXD3 hold time from RCLK3 rising edge ²	5.00	_	ns		
108	CD3 setup Time to RCLK3 rising edge	5.00	_	ns		

Table 22. NMSI External Clock Timing

¹ The ratios SyncCLK/RCLK3 and SyncCLK/TCLK3 must be greater than or equal to 2.25/1.

² Also applies to $\overline{\text{CD}}$ and $\overline{\text{CTS}}$ hold time when they are used as an external sync signal

Table 23 provides the NMSI internal clock timing.

Table 23. NMSI Internal Clock Timing

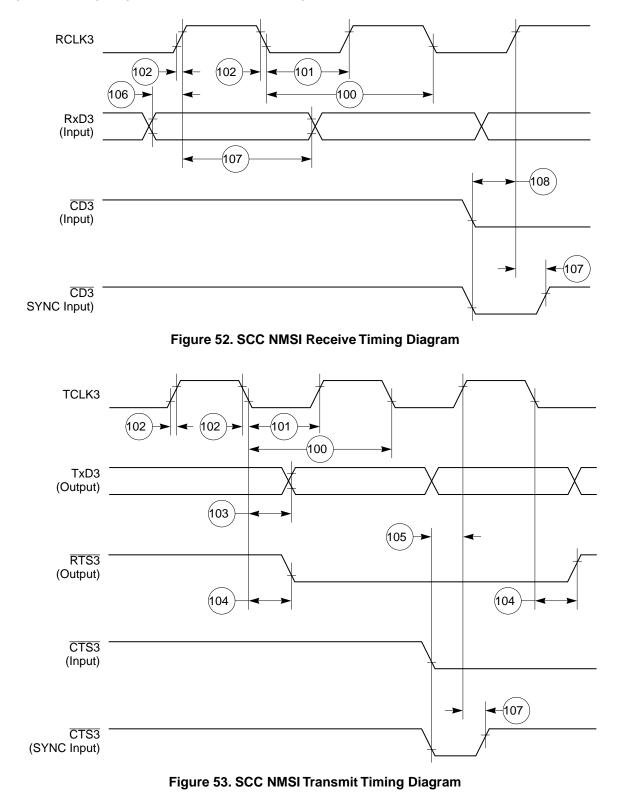
Num	Characteristic	All Fi	Unit	
Num	Characteristic	Min	Max	Unit
100	RCLK3 and TCLK3 frequency ¹	0.00	SYNCCLK/3	MHz
102	RCLK3 and TCLK3 rise/fall time	_	_	ns
103	TXD3 active delay (from TCLK3 falling edge)	0.00	30.00	ns
104	RTS3 active/inactive delay (from TCLK3 falling edge)	0.00	30.00	ns
105	CTS3 setup time to TCLK3 rising edge	40.00	_	ns
106	RXD3 setup time to RCLK3 rising edge	40.00	_	ns
107	RXD3 hold time from RCLK3 rising edge ²	0.00	_	ns
108	CD3 setup time to RCLK3 rising edge	40.00	—	ns

¹ The ratios SyncCLK/RCLK3 and SyncCLK/TCLK3 must be greater or equal to 3/1.

² Also applies to \overline{CD} and \overline{CTS} hold time when they are used as an external sync signals

CPM Electrical Characteristics

Figure 52 through Figure 54 show the NMSI timings.



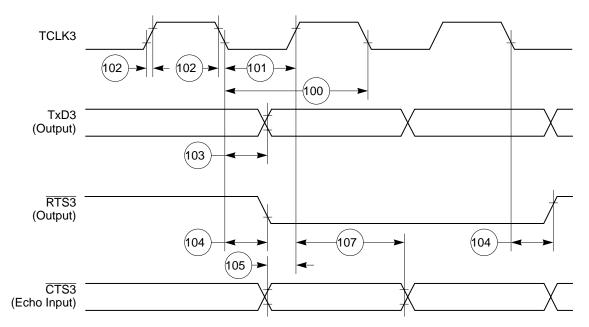


Figure 54. HDLC Bus Timing Diagram

13.7 Ethernet Electrical Specifications

Table 24 provides the Ethernet timings as shown in Figure 55 to Figure 57.

Table 24. Ethernet Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
120	CLSN width high	40	_	ns
121	RCLK3 rise/fall time	—	15	ns
122	RCLK3 width low	40	—	ns
123	RCLK3 clock period ¹	80	120	ns
124	RXD3 setup time	20	_	ns
125	RXD3 hold time	5	_	ns
126	RENA active delay (from RCLK3 rising edge of the last data bit)	10	_	ns
127	RENA width low	100	_	ns
128	TCLK3 rise/fall time	—	15	ns
129	TCLK3 width low	40	_	ns
130	TCLK3 clock period ¹	99	101	ns
131	TXD3 active delay (from TCLK3 rising edge)	-	50	ns
132	TXD3 inactive delay (from TCLK3 rising edge)	6.5	50	ns
133	TENA active delay (from TCLK3 rising edge)	10	50	ns

Num	All Characteristic Frequencie	All Frequencies		Frequenc				Unit
		Min	Max					
134	TENA inactive delay (from TCLK3 rising edge)	10	50	ns				
138	CLKO1 low to SDACK asserted ²	_	20	ns				
139	CLKO1 low to SDACK negated ²		20	ns				

Table 24. Ethernet Timing (continued)

¹ The ratios SyncCLK/RCLK3 and SyncCLK/TCLK3 must be greater or equal to 2/1.

² SDACK is asserted whenever the SDMA writes the incoming frame DA into memory.

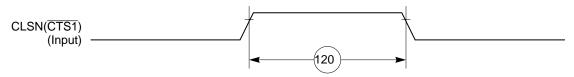


Figure 55. Ethernet Collision Timing Diagram

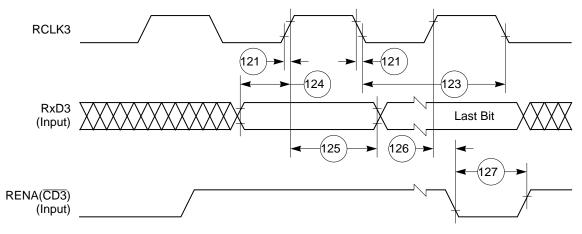


Figure 56. Ethernet Receive Timing Diagram

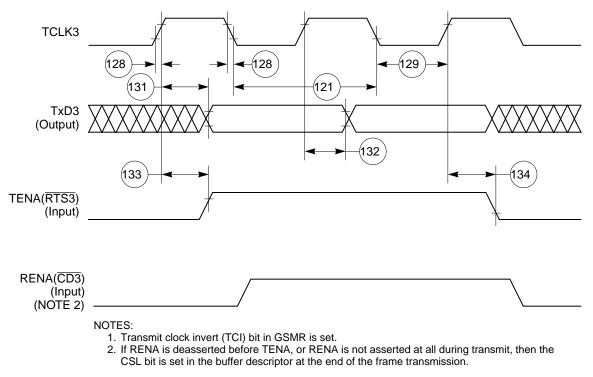


Figure 57. Ethernet Transmit Timing Diagram

13.8 SMC Transparent AC Electrical Specifications

Table 25 provides the SMC transparent timings as shown in Figure 58.

Num	Characteristic	A Freque		Unit
		Min	Max	
150	SMCLK clock period ¹	100	_	ns
151	SMCLK width low	50	_	ns
151A	SMCLK width high	50	_	ns
152	SMCLK rise/fall time		15	ns
153	SMTXD active delay (from SMCLK falling edge)	10	50	ns
154	SMRXD/SMSYNC setup time	20	_	ns
155	RXD1/SMSYNC hold time	5		ns

¹ SyncCLK must be at least twice as fast as SMCLK.

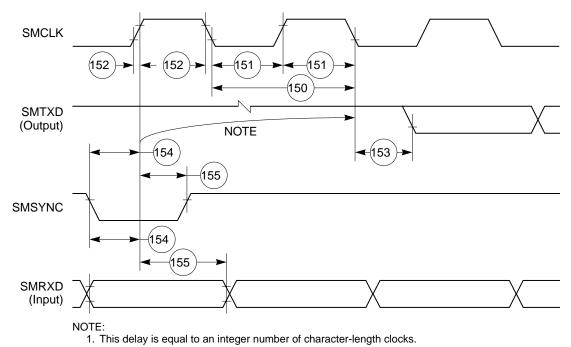


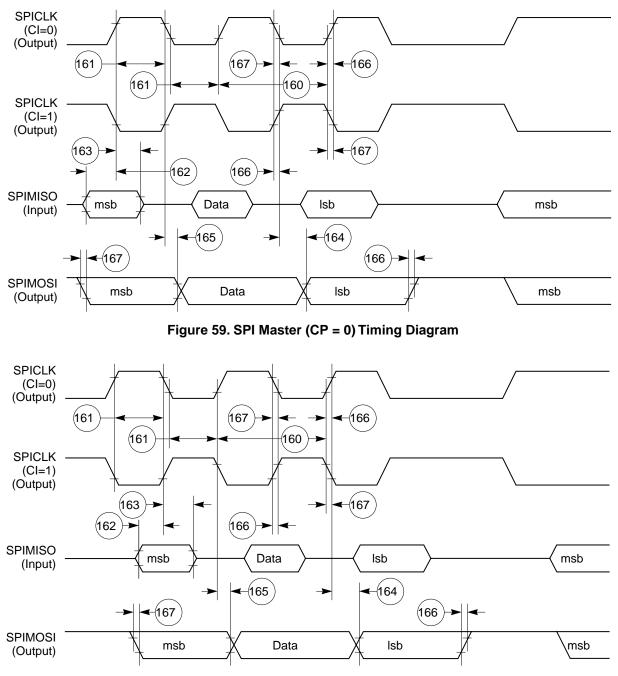
Figure 58. SMC Transparent Timing Diagram

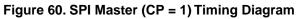
13.9 SPI Master AC Electrical Specifications

Table 26 provides the SPI master timings as shown in Figure 59 and Figure 60.

Table 26. SPI Master Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
160	MASTER cycle time	4	1024	t _{cyc}
161	MASTER clock (SCK) high or low time	2	512	t _{cyc}
162	MASTER data setup time (inputs)	15	_	ns
163	Master data hold time (inputs)	0	_	ns
164	Master data valid (after SCK edge)	_	10	ns
165	Master data hold time (outputs)	0	_	ns
166	Rise time output	—	15	ns
167	Fall time output	—	15	ns





13.10 SPI Slave AC Electrical Specifications

Table 27 provides the SPI slave timings as shown in Figure 61 and Figure 62.

Num	Characteristic	All Frequencies		Unit
		Min	Max	
170	Slave cycle time	2	_	t _{cyc}
171	Slave enable lead time	15	_	ns
172	Slave enable lag time	15	_	ns
173	Slave clock (SPICLK) high or low time	1	_	t _{cyc}
174	Slave sequential transfer delay (does not require deselect)	1	_	t _{cyc}
175	Slave data setup time (inputs)	20	_	ns
176	Slave data hold time (inputs)	20	_	ns
177	Slave access time	_	50	ns



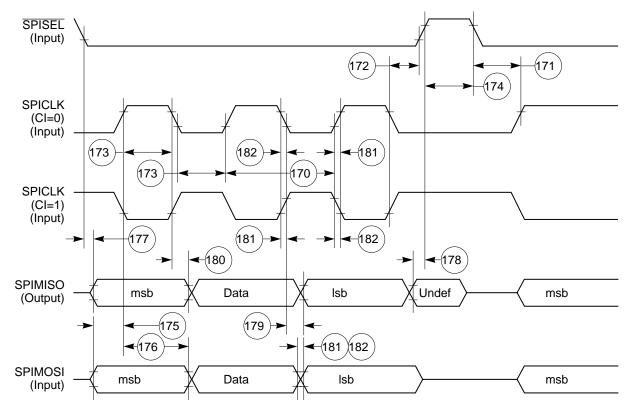
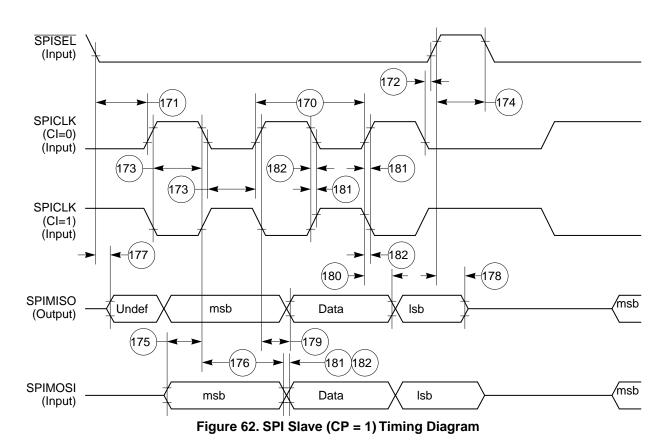


Figure 61. SPI Slave (CP = 0) Timing Diagram



13.11 I²C AC Electrical Specifications

Table 28 provides the I^2C (SCL < 100 KHz) timings.

Table 28. I²C Timing (SCL < 100 KHz)

Num	Characteristic	A Freque	Unit	
		Min	Max	
200	SCL clock frequency (slave)	0	100	KHz
200	SCL clock frequency (master) ¹	1.5	100	KHz
202	Bus free time between transmissions	4.7	_	μs
203	Low period of SCL	4.7	_	μs
204	High period of SCL	4.0	_	μs
205	Start condition setup time	4.7	_	μs
206	Start condition hold time	4.0	_	μs
207	Data hold time	0	_	μs
208	Data setup time	250	_	ns
209	SDL/SCL rise time		1	μs

Num	Characteristic		All Frequencies		
		Min Max	Max		
210	SDL/SCL fall time	_	300	ns	
211	Stop condition setup time	4.7	_	μs	

Table 28. I²C Timing (SCL < 100 KHz) (continued)

SCL frequency is given by SCL = BRGCLK_frequency / ((BRG register + 3) * pre_scaler * 2). The ratio SyncClk/(BRGCLK/pre_scaler) must be greater than or equal to 4/1.

Table 29 provides the I^2C (SCL > 100 KHz) timings.

Num	um Characteristic Expression –		All Freq	uencies	Unit
num	Characteristic	Expression	Min	Max	
200	SCL clock frequency (slave)	fSCL	0	BRGCLK/48	Hz
200	SCL clock frequency (master) ¹	fSCL	BRGCLK/16512	BRGCLK/48	Hz
202	Bus free time between transmissions	_	1/(2.2 * fSCL)	_	S
203	Low period of SCL	_	1/(2.2 * fSCL)	_	S
204	High period of SCL	_	1/(2.2 * fSCL)	_	s
205	Start condition setup time	_	1/(2.2 * fSCL)	_	s
206	Start condition hold time	_	1/(2.2 * fSCL)	_	s
207	Data hold time	_	0	_	s
208	Data setup time	—	1/(40 * fSCL)	—	s
209	SDL/SCL rise time	—	—	1/(10 * fSCL)	s
210	SDL/SCL fall time	—	—	1/(33 * fSCL)	s
211	Stop condition setup time	—	1/2(2.2 * fSCL)	_	s

 ¹ SCL frequency is given by SCL = BrgClk_frequency / ((BRG register + 3) * pre_scaler * 2). The ratio SyncClk/(Brg_Clk/pre_scaler) must be greater than or equal to 4/1.

USB Electrical Characteristics

Figure 63 shows the I^2C bus timing.

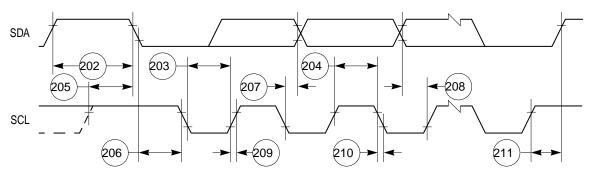


Figure 63. I²C Bus Timing Diagram

14 USB Electrical Characteristics

This section provides the AC timings for the USB interface.

14.1 USB Interface AC Timing Specifications

The USB Port uses the transmit clock on SCC1. Table 30 lists USB interface timings.

Table 30. USB Interface AC Timing Specification	B Interface AC Timing Specification	ons
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Name	Characteristic		All Frequencies		
		Min Max	Unit		
	USBCLK frequency of operation ¹ Low speed Full speed	6		MHz MHz	
US4	USBCLK duty cycle (measured at 1.5 V)	45	55	%	

¹ USBCLK accuracy should be +- 500ppm or better. USBCLK may be stopped to conserve power.

15 FEC Electrical Characteristics

This section provides the AC electrical specifications for the Fast Ethernet controller (FEC). Note that the timing specifications for the MII signals are independent of system clock frequency (part speed designation). Also, MII signals use TTL signal levels compatible with devices operating at either 5.0 V or 3.3 V.

15.1 MII and Reduced MII Receive Signal Timing

The receiver functions correctly up to a MII_RX_CLK maximum frequency of 25 MHz +1%. The Reduced MII (RMII) receiver functions correctly up to a RMII_REFCLK maximum frequency of 50 MHz +1%. There is no minimum frequency requirement. In addition, the processor clock frequency must exceed the MII_RX_CLK frequency - 1%.

Table 31 provides information on the MII receive signal timing.

Table 31. MII Receive Signal Timing

Num	Characteristic	Min	Max	Unit
M1	MII_RXD[3:0], MII_RX_DV, MII_RX_ER to MII_RX_CLK setup	5	_	ns
M2	MII_RX_CLK to MII_RXD[3:0], MII_RX_DV, MII_RX_ER hold	5	_	ns
M3	MII_RX_CLK pulse width high	35%	65%	MII_RX_CLK period
M4	MII_RX_CLK pulse width low	35%	65%	MII_RX_CLK period
M1_R MII	RMII_RXD[1:0], RMII_CRS_DV, RMII_RX_ERR to RMII_REFCLK setup	4	—	ns
M2_R MII	RMII_REFCLK to RMII_RXD[1:0], RMII_CRS_DV, RMII_RX_ERR hold	2	—	ns

Figure 64 shows MII receive signal timing.

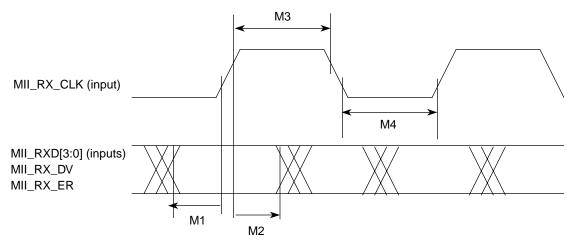


Figure 64. MII Receive Signal Timing Diagram

15.2 MII and Reduced MII Transmit Signal Timing

The transmitter functions correctly up to a MII_TX_CLK maximum frequency of 25 MHz +1%. There is no minimum frequency requirement. In addition, the processor clock frequency must exceed the MII_TX_CLK frequency - 1%.

Table 32 provides information on the MII transmit signal timing,.

Table 32. MII Transmit Signal Timing

Num	Characteristic	Min	Max	Unit
M5	MII_TX_CLK to MII_TXD[3:0], MII_TX_EN, MII_TX_ER invalid	5	_	ns
M6	MII_TX_CLK to MII_TXD[3:0], MII_TX_EN, MII_TX_ER valid	—	25	ns
M7	MII_TX_CLK pulse width high	35%	65%	MII_TX_CLK period
M8	MII_TX_CLK pulse width low	35%	65%	MII_TX_CLK period

Num	Characteristic	Min	Max	Unit
M20_R MII	RMII_TXD[1:0], RMII_TX_EN to RMII_REFCLK setup	4	_	ns
M21_R MII	RMII_TXD[1:0], RMII_TX_EN data hold from RMII_REFCLK rising edge	2	_	ns

Table 32. MII Transmi	t Signal Timing (continued)
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Figure 65 shows the MII transmit signal timing diagram.

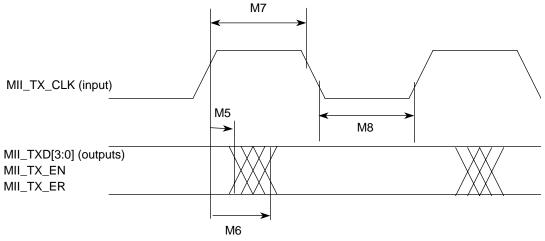


Figure 65. MII Transmit Signal Timing Diagram

15.3 MII Async Inputs Signal Timing (MII_CRS, MII_COL)

Table 33 provides information on the MII async inputs signal timing.

Table 33. MII Async Inputs Signal Timing

Num	Characteristic	Min	Мах	Unit
M9	MII_CRS, MII_COL minimum pulse width	1.5	_	MII_TX_CLK period

Figure 66 shows the MII asynchronous inputs signal timing diagram.

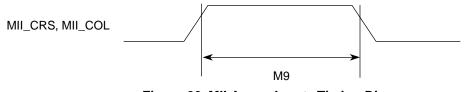


Figure 66. MII Async Inputs Timing Diagram

15.4 MII Serial Management Channel Timing (MII_MDIO, MII_MDC)

Table 34 provides information on the MII serial management channel signal timing. The FEC functions correctly with a maximum MDC frequency in excess of 2.5 MHz. The exact upper bound is under investigation.

Num	Characteristic	Min	Max	Unit
M10	MII_MDC falling edge to MII_MDIO output invalid (minimum propagation delay)	0	_	ns
M11	MII_MDC falling edge to MII_MDIO output valid (max prop delay)	_	25	ns
M12	MII_MDIO (input) to MII_MDC rising edge setup	10	_	ns
M13	MII_MDIO (input) to MII_MDC rising edge hold	0	_	ns
M14	MII_MDC pulse width high	40%	60%	MII_MDC period
M15	MII_MDC pulse width low	40%	60%	MII_MDC period

Table 34. MII Serial Management Channel Timing

Figure 67 shows the MII serial management channel timing diagram.

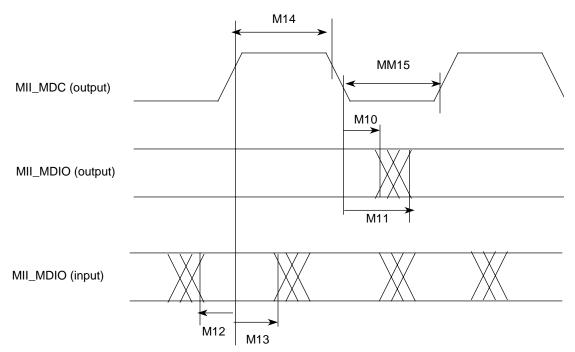


Figure 67. MII Serial Management Channel Timing Diagram

16 Mechanical Data and Ordering Information

Table 35 identifies the packages and operating frequencies available for the MPC875/870.

Package Type	Temperature (Tj)	Frequency (MHz)	Order Number
Plastic ball grid array (VR suffix)	0°C to 95°C	66	TBD
		80	TBD
		120	TBD
Plastic ball grid array (CVR suffix)	-40°C to 100°C	TBD	TBD

Table 35. Available MPC875/870 Packages/Frequencies

16.1 Pin Assignments

Figure 68 shows the JEDEC pinout of the PBGA package as viewed from the top surface. For additional information, see the *MPC866 PowerQUICC Family User's Manual*.

NOTE

The pin numbering starts with B2 in order to conform to the JEDEC standard for 23mm body size using a 16×16 array.

NOTE: This is the top view of the device.

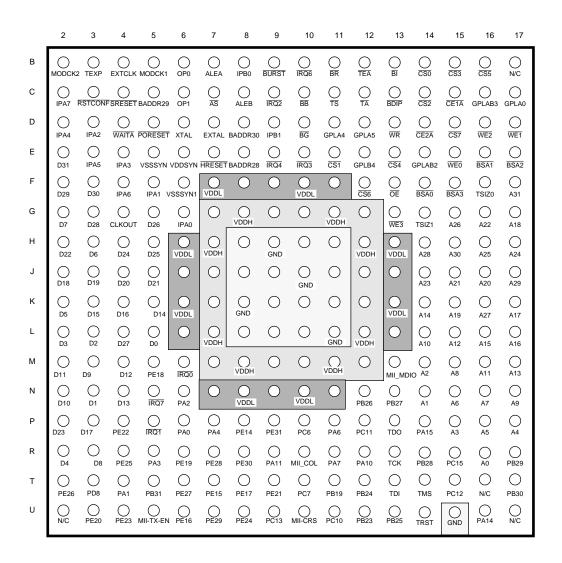


Figure 68. Pinout of the PBGA Package - JEDEC Standard

Mechanical Data and Ordering Information

Table 36 contains a list of the MPC875/870 input and output signals and shows multiplexing and pin assignments.

Name	Pin Number	Туре
A[0:31]	R16, N14, M14, P15, P17, P16, N15, N16, M15, N17, L14, M16, L15, M17, K14, L16, L17, K17, G17, K15, J16, J15, G16, J14, H17, H16, G15, K16, H14, J17, H15, F17	Bidirectional Three-state (3.3 V only)
TSIZ0 REG	F16	Bidirectional Three-state (3.3 V only)
TSIZ1	G14	Bidirectional Three-state (3.3 V only)
RD/WR	D13	Bidirectional Three-state (3.3 V only)
BURST	B9	Bidirectional Three-state (3.3 V only)
BDIP GPL_B5	C13	Output
TS	C11	Bidirectional Active pull-up (3.3 V only)
TA	C12	Bidirectional Active pull-up (3.3 V only)
TEA	B12	Open-drain
BI	B13	Bidirectional Active pull-up (3.3 V only)
IRQ2 RSV	C9	Bidirectional Three-state (3.3 V only)
IRQ4 KR RETRY SPKROUT	E9	Bidirectional Three-state (3.3 V only)
D[0:31]	L5, N3, L3, L2, R2, K2, H3, G2, R3, M3, N2, M2, M4, N4, K5, K3, K4, P3, J2, J3, J4, J5, H2, P2, H4, H5, G5, L4, G3, F2, F3, E2	Bidirectional Three-state (3.3 V only)
CR IRQ3	E10	Input
FRZ IRQ6	B10	Bidirectional Three-state (3.3 V only)
BR	B11	Bidirectional (3.3 V only)
BG	D10	Bidirectional (3.3 V only)
BB	C10	Bidirectional Active pull-up (3.3 V only)
IRQ0	M6	Input (3.3 V only)
IRQ1	P5	Input (3.3 V only)
IRQ7	N5	Input (3.3 V only)

Table 36. Pin Assignments - JEDEC Standard

Name	Pin Number	Туре	
CS[0:5]	B14, E11, C14, B15, E13, B16	Output	
CS6 CE1_B	F12 Output		
CS7 CE2_B	D15	Output	
WE0 BS_B0 IORD	E15	Output	
WE1 BS_B1 IOWR	D17	Output	
WE2 BS_B2 PCOE	D16	Output	
WE3 BS_B3 PCWE	G13	Output	
BS_A[0:3]	F14, E16, E17, F15	Output	
GPL_A0 GPL_B0	C17	Output	
OE GPL_A1 GPL_B1	F13	Output	
GPL_A[2:3] GPL_B[2:3] CS[2–3]	E14, C16	Output	
UPWAITA GPL_A4	D11	Bidirectional (3.3 V only)	
UPWAITB GPL_B4	E12	Bidirectional	
GPL_A5	D12	Output	
PORESET	D5	Input (3.3 V only)	
RSTCONF	C3	Input (3.3 V only)	
HRESET	E7	Open-drain	
SRESET	C4	Open-drain	
XTAL	D6 Analog out		
EXTAL	D7	Analog input (3.3 V only)	
CLKOUT	G4	Output	
EXTCLK	B4	Input (3.3 V only)	
TEXP	B3	Output	

Table 36. Pin Assignments -	JEDEC Standard (continued)
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Name	Pin Number	Туре
ALE_A	B7	Output
CE1_A	C15	Output
CE2_A	D14	Output
WAIT_A	D4	Input (3.3 V only)
IP_A0	G6	Input (3.3 V only)
IP_A1	F5	Input (3.3 V only)
IP_A2 IOIS16_A	D3	Input (3.3 V only)
IP_A3	E4	Input (3.3 V only)
IP_A4	D2	Input (3.3 V only)
IP_A5	E3	Input (3.3 V only)
IP_A6	F4	Input (3.3 V only)
IP_A7	C2	Input (3.3 V only)
ALE_B DSCK	C8	Bidirectional Three-state (3.3 V only)
IP_B[0:1] IWP[0:1] VFLS[0:1]	B8, D9	Bidirectional (3.3 V only)
OP0	B6	Bidirectional (3.3 V only)
OP1	C6	Output
OP2 MODCK1 STS	B5	Bidirectional (3.3 V only)
OP3 MODCK2 DSDO	B2	Bidirectional (3.3 V only)
BADDR[28:29]	E8, C5	Output
BADDR30 REG	D8	Output
ĀS	C7	Input (3.3 V only)
PA15 USBRXD	P14	Bidirectional
PA14 USBOE	U16	Bidirectional (Optional: Open-drain)
PA11 RXD4 MII1-TXD0 RMII1-TXD0	R9	Bidirectional (Optional: Open-drain) (5-V tolerant)

Name	Pin Number	Туре
PA10 MII1-TXERR TIN4 CLK7	R12	Bidirectional (Optional: Open-drain) (5-V tolerant)
PA7 CLK1 BRGO1 TIN1	R11	Bidirectional
PA6 CLK2 TOUT1	P11	Bidirectional
PA4 CTS4 MII1-TXD1 RMII-TXD1	P7	Bidirectional
PA3 MII1-RXER RMII1-RXER BRGO3	R5	Bidirectional (5-V tolerant)
PA2 MII1-RXDV RMII1-CRS_DV TXD4	N6	Bidirectional (5-V tolerant)
PA1 MII1-RXD0 RMII1-RXD0 BRGO4	T4	Bidirectional (5-V tolerant)
PA0 MII1-RXD1 RMII1-RXD1 TOUT4	P6	Bidirectional (5-V tolerant)
PB31 SPISEL MII1 - TXCLK RMII1-REFCLK	T5	Bidirectional (Optional: Open-drain) (5-V tolerant)
PB30 SPICLK	T17	Bidirectional (Optional: Open-drain) (5-V tolerant)
PB29 SPIMOSI	R17	Bidirectional (Optional: Open-drain) (5-V tolerant)
PB28 SPIMISO BRGO4	R14	Bidirectional (Optional: Open-drain) (5-V tolerant)
PB27 I2CSDA BRGO1	N13	Bidirectional (Optional: Open-drain)

Name	Pin Number	Туре
PB26 I2CSCL BRGO2	N12	Bidirectional (Optional: Open-drain)
PB25 SMTXD1	U13	Bidirectional (Optional: Open-drain) (5-V tolerant)
PB24 SMRXD1	T12	Bidirectional (Optional: Open-drain) (5-V tolerant)
PB23 SDACK1 SMSYN1	U12	Bidirectional (Optional: Open-drain)
PB19 MII1-RXD3 RTS4	T11	Bidirectional (Optional: Open-drain)
PC15 DREQ0 L1ST1	R15	Bidirectional (5-V tolerant)
PC13 MII1-TXD3 SDACK1	U9	Bidirectional (5-V tolerant)
PC12 MII1-TXD2 TOUT1	T15	Bidirectional (5-V tolerant)
PC11 USBRXP	P12	Bidirectional
PC10 USBRXN TGATE1	U11	Bidirectional
PC7 CTS4 L1TSYNCB USBTXP	T10	Bidirectional (5-V tolerant)
PC6 CD4 L1RSYNCB USBTXN	P10	Bidirectional (5-V tolerant)
PD8 RXD4 MII-MDC RMII-MDC	ТЗ	Bidirectional (5-V tolerant)
PE31 CLK8 L1TCLKB MII1-RXCLK	P9	Bidirectional (Optional: Open-drain)

Name	Pin Number	Туре
PE30 L1RXDB MII1-RXD2	R8	Bidirectional (Optional: Open-drain)
PE29 MII2-CRS	U7	Bidirectional (Optional: Open-drain)
PE28 TOUT3 MII2-COL	R7	Bidirectional (Optional: Open-drain)
PE27 L1RQB MII2-RXERR RMII2-RXERR	Т6	Bidirectional (Optional: Open-drain)
PE26 L1CLKOB MII2-RXDV RMII2-CRS_DV	T2	Bidirectional (Optional: Open-drain)
PE25 RXD4 MII2-RXD3 L1ST2	R4	Bidirectional (Optional: Open-drain)
PE24 SMRXD1 BRGO1 MII2-RXD2	U8	Bidirectional (Optional: Open-drain)
PE23 TXD4 MII2-RXCLK L1ST1	U4	Bidirectional (Optional: Open-drain)
PE22 TOUT2 MII2-RXD1 RMII2-RXD1 SDACK1	P4	Bidirectional (Optional: Open-drain)
PE21 TOUT1 MII2-RXD0 RMII2-RXD0	Т9	Bidirectional (Optional: Open-drain)
PE20 MII2-TXER	U3	Bidirectional (Optional: Open-drain)
PE19 L1TXDB MII2-TXEN RMII2-TXEN	R6	Bidirectional (Optional: Open-drain)
PE18 SMTXD1 MII2-TXD3	M5	Bidirectional (Optional: Open-drain)

Name	Pin Number	Туре
PE17 TIN3 CLK5 BRGO3 SMSYN1 MII2-TXD2	Τ8	Bidirectional (Optional: Open-drain)
PE16 L1RCLKB CLK6 MII2-TXCLK RMII2-REFCLK	U6	Bidirectional (Optional: Open-drain)
PE15 TGATE1 MII2-TXD1 RMII2-TXD1	Τ7	Bidirectional
PE14 MII2-TXD0 RMII2-TXD0	P8	Bidirectional
TMS	T14	Input (5-V tolerant)
TDI DSDI	T13	Input (5-V tolerant)
TCK DSCK	R13	Input (5-V tolerant)
TRST	U14	Input (5-V tolerant)
TDO DSDO	P13	Output (5-V tolerant)
MII1_CRS	U10	Input
MII_MDIO	M13	Bidirectional (5-V tolerant)
MII1_TX_EN	U5	Output (5-V tolerant)
MII1_COL	R10	Input
VSSSYN	E5	PLL analog GND
VSSSYN1	F6	PLL analog GND
VDDSYN	E6	PLL analog VDD
GND	H8, H9, H10, H11, J8, J9, J10, J11, K8, K9, K10, K11, L8, L9, L10, L11, U15	Power
VDDL	F7, F8, F9, F10, F11, H6, H13, J6, J13, K6, K13, L6, L13, N7, N8, N9, N10, N11	Power

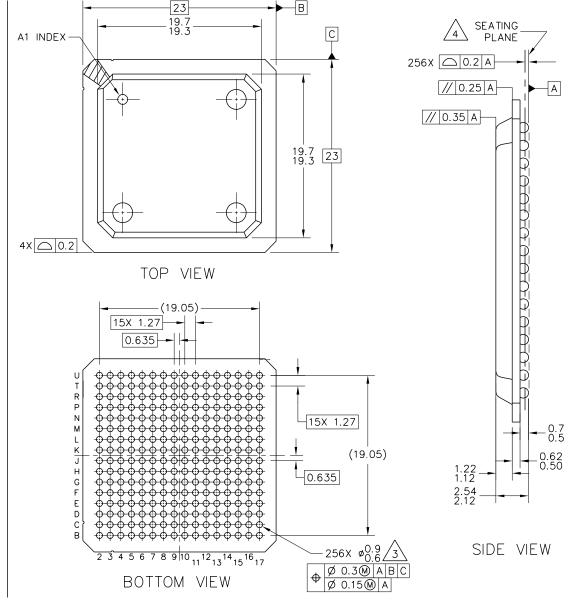
Mechanical Data and Ordering Information

Name	Pin Number	Туре
VDDH	G7, G8, G9, G10, G11, G12, H7, H12, J7, J12, K7, K12, L7, L12, M7, M8, M9, M10, M11, M12	Power
N/C	B17, T16, U2, U17	No-connect

Table 36. Pin Assignments -	JEDEC Standard (continued)
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16.2 Mechanical Dimensions of the PBGA Package

Figure 69 shows the mechanical dimensions of the PBGA package.



NOTES:

- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
- 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
- 3. MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A.
- 4. DATUM A, THE SEATING PLANE, IS DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.
- **Note:** Solder sphere composition is 95.5% Sn 45% Ag 0.5% Cu for MPC875/870VRXXX Solder sphere composition is 62% Sn 36% Pb 2% Ag for MPC875/870ZTXXX

Figure 69. Mechanical Dimensions and Bottom Surface Nomenclature of the PBGA Package

17 Document Revision History

Table 37 lists significant changes between revisions of this hardware specification.

Revision	Date	Changes
0	2/2003	Initial release
0.1	3/2003	Took out the timeslot assigner and changed the SCC for SCC3 to SCC4
0.2	5/2003	Changed the package drawing, removed all references to Data Parity. Changed the SPI Master Timing Specs. 162 and 164. Added the RMII and USB Timing. Added the 80 MHz timing.
0.3	5/2003	Made sure the pin types were correct. Changed the Feature List so it agreed with the MPC885.
0.4	5/2003	Corrected the signals that had overlines on them. Made corrections on two pins that were typos.
0.5	5/2003	Changed the pin descriptions for PD8 and PD9
0.6	5/2003	Changed a few typos. Put back the I2C. Put in the new Reset configuration, corrected the USB timing
0.7	6/2003	Changed the pin descriptions per the June 22 spec, removed Utopia from the pin descriptions, changed PADIR, PBDIR, PCDIR and PDDIR to be 0 in the Mandatory Reset Config
0.8	8/2003	Added the reference to USB 2.0 to the Features list and removed 1.1 from USB on the block diagrams
0.9	8/2003	Changed the USB description to Full/Low Speed Compatible
1.0	9/2003	Added the DSP information in the features list Put a new sentence under Mechanical Dimensions Fixed table formatting Nontechnical edits Released to the external web
1.1	10/2003	Added TDMb to the MPC875 Feature List, the MPC875 Block Diagram, added 13.5 Serial Interface AC Electrical Specifications, and removed TDMa from the pins descriptions.

Table 37. Document Revision History

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